CN100B110-*

EVALUATION DATA

型式データ

INDEX

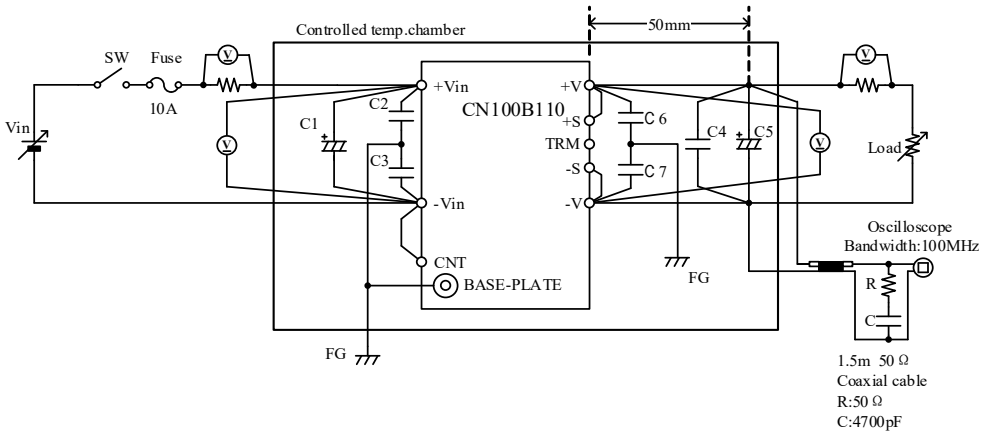
使用記号　Terminology used

	Definition	
Vin ·····	入力電圧	Input voltage
Vo ·····	出力電圧	Output voltage
Vcnt·····	CNT電圧	CNT voltage
Iin ·····	入力電流	Input current
Io ·····	出力電流	Output current
Tbp ·····	ベースプレート温度	Base-plate temperature
Ta ·····	周囲温度	Ambient temperature
f ·····	周波数	Frequency

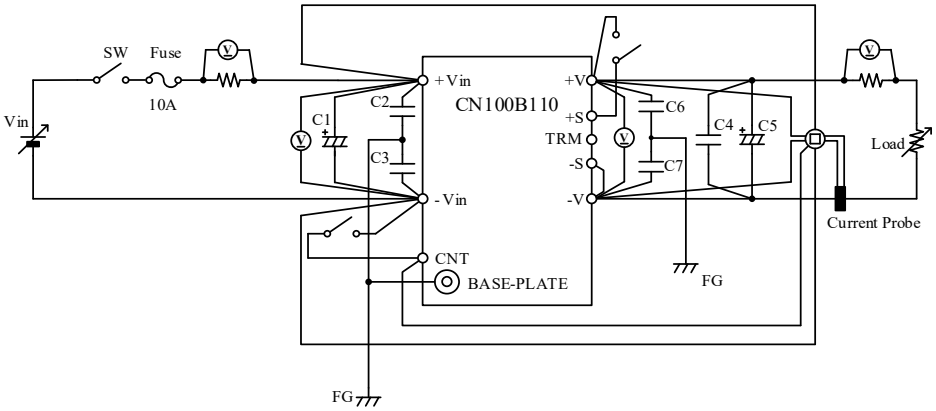
1. 評価方法　Evaluation Method

1.1 測定回路　Measurement Circuits

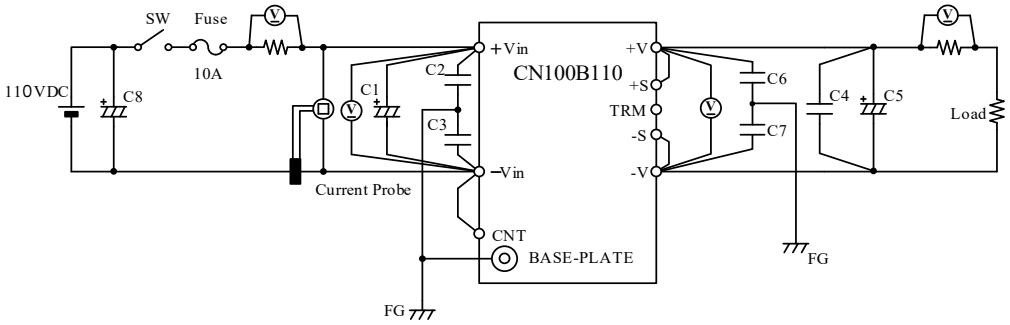
(1) 静特性、過電流保護特性、出力リップル・ノイズ波形
Steady state characteristics, Over current protection (OCP) characteristics and Output ripple and noise waveform



(2) 過渡応答、過電圧保護特性、その他
Dynamic response,Over voltage protection (OVP) characteristics and Other characteristics



(3) 入力サージ電流（突入電流）特性
Inrush current characteristics

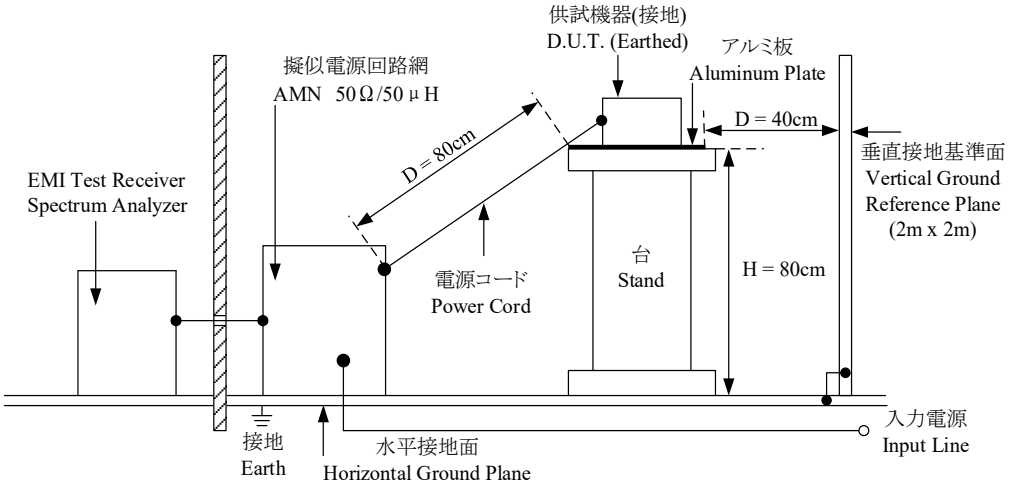


C1 : 100μF Electrolytic Capacitor
C2,C3 : 4700pF Ceramic Capacitor
C4 : 2.2μF Ceramic Capacitor
C6,C7 : 0.022μF Film Capacitor
C8 : 20000μF Electrolytic Capacitor

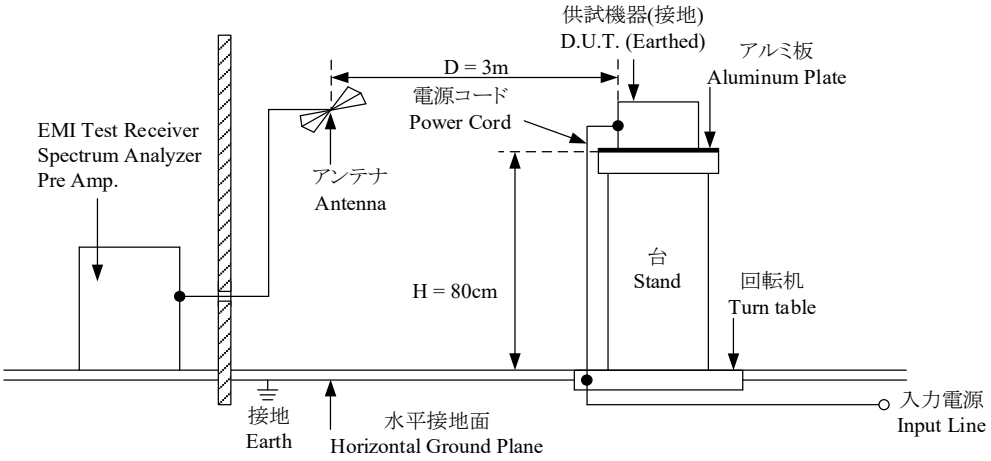
C5 : 5V- 1000μF Solid Capacitor
: 12V- 680μF Solid Capacitor
: 15V- 680μF Solid Capacitor
: 24V- 220μF Electrolytic Capacitor
: 48V- 220μF x2 Series Electrolytic Capacitor

(4) EMI特性 Electro-Magnetic Interference characteristics

(a) 雑音端子電圧 (帰還ノイズ) Conducted Emission Noise

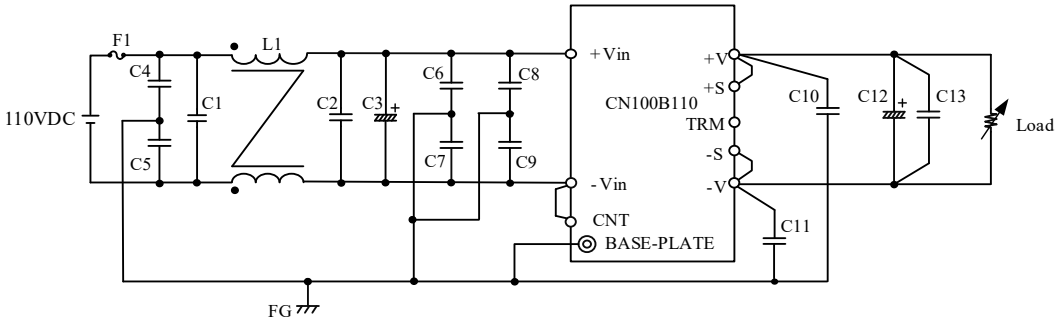


(b) 雑音電界強度(輻射ノイズ) Radiated Emission Noise



*入出力ケーブルとしてシールドケーブルを使用
Shielded cable used to input and output cable.

VCCI class A対応アプリケーションシステム
VCCI class A application system



C1 : 1.5μF Film Capacitor
C2 : 1.5μF Film Capacitor
C3 : 100μF Electrolytic Capacitor
C4,C5 : 100pF Ceramic Capacitor
C6,C7,C8,C9 : 4700pF Ceramic Capacitor
C10,C11 : 0.022μF Film Capacitor
C13 : 2.2μF Ceramic Capacitor

C12 : 5V- 1000μF Solid Capacitor
: 12V- 680μF Solid Capacitor
: 15V- 680μF Solid Capacitor
: 24V- 220μF Electrolytic Capacitor
: 48V- 220μF x2 Series Electrolytic Capacitor
F1 : 10A
L1 : 2mH

*詳細な周辺パラメータ情報(参照用)

The detailed peripheral parameter information (for reference)

	SYMBOL		PRODUCT TYPE	ITEM DESCRIPTION	NOTE	MANUFACTURER
1	F1		Fuse	WN30-10-P	500VDC, 10A	WALTER
2	C1,C2		Cap., Film	MDX22W155K-F	450VDC , 1.5μ	NITSUKO
3	C3		Cap., Elect	EKXJ201ELL101MJ35S	200V, 100μ	NI-CHEMI
4	C4,C5		Cap.,Ceramic(AC)	DE1B3RA101KJ4BN01F	250V, 100p	MURATA
5	C6,C7,C8,C9		Cap.,Ceramic(AC)	DE1E3KX472MJ4BN04F	250V, 4,700p	MURATA
6	C10,C11		Cap., Film	MMCF0630K22300000100	630V, 0.022μ	NISSEI
7	C12	5V Model	Cap., Solid	APSG160ELL102MJB5S	16V, 1,000μ	NI-CHEMI
8		12V Model	Cap., Solid	APSG250ELL681MJB5S	25V, 680μ	NI-CHEMI
9		15V Model	Cap., Solid	APSG250ELL681MJB5S	25V, 680μ	NI-CHEMI
10		24V Model	Cap., Elect	ELXY500ELL221MJ25S	50V, 220μ	NI-CHEMI
11		48V Model	Cap., Elect ×2 Series	ELXY500ELL221MJ25S	50V, 220μ ×2	NI-CHEMI
12	C13		MLCC	C3225X7R2A225KT	100V, 2.2μ	TDK
13	L1		Noise Filter Coil	TC580020S	2mH, 8A	TNC

1.2 使用測定機器　List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	AMN	SCHWARZBECK	NNLK8121
2	ANTENNA(BI-LOG ANTENNA)	TESEQ	CBL6111D
3	CONTROLLED TEMP. CHAMBER	ESPEC CORP.	SU-662
4	CURRENT PROBE	YOKOGAWA ELECT.	701930
5	CURRENT PROBE AMPLIFIER	YOKOGAWA ELECT.	700938
6	CVCF	KIKUSUI	PCR2000L
7	DC POWER SUPPLY	TDK-Lambda	GEN200-25
8	DIGITAL MULTIMETER	Agilent	34970A
9	DIGITAL POWER METER	YOKOGAWA ELECT.	WT210
10	DIGITAL STORAGE OSCILLOSCOPE	YOKOGAWA ELECT.	DLM2054
11	DYNAMIC DUMMY LOAD	Chroma	63203
12	EMI TEST RECEIVER SPECTRUM ANALYZER	ROHDE & SCHWARZ	ESCI
13	PRE AMP.	SONOMA	310N
14	SHUNT RESISTER	YOKOGAWA ELECT.	2215

2. 特性データ Characteristics

2.1 静特性 Steady state data
(1) 入力変動、負荷変動、温度変動 Line regulation, Load regulation, Temperature drift

5V

1. Line regulation and Load regulation　　Condition　Tbp : 25℃

Io \ Vin	43VDC	72VDC	110VDC	160VDC	Line regulation	
0%	4.989V	4.989V	4.989V	4.989V	0mV	0.000%
50%	4.989V	4.989V	4.989V	4.989V	0mV	0.000%
100%	4.989V	4.989V	4.989V	4.988V	0mV	0.000%
Load	0mV	0mV	0mV	1mV		
regulation	0.000%	0.000%	0.000%	0.020%		

2. Temperature drift　　Conditions　Vin : 110VDC
Io : 100%

Tbp	-40℃	+25℃	+100℃	Temperature stability	
Vo	4.996V	4.989V	4.990V	7mV	0.143%

12V

1. Line regulation and Load regulation　　Condition　Tbp : 25℃

Io \ Vin	43VDC	72VDC	110VDC	160VDC	Line regulation	
0%	11.950V	11.950V	11.950V	11.950V	0mV	0.000%
50%	11.949V	11.949V	11.949V	11.949V	0mV	0.000%
100%	11.948V	11.948V	11.948V	11.948V	0mV	0.000%
Load	2mV	2mV	2mV	2mV		
regulation	0.017%	0.017%	0.017%	0.017%		

2. Temperature drift　　Conditions　Vin : 110VDC
Io : 100%

Tbp	-40℃	+25℃	+100℃	Temperature stability	
Vo	11.963V	11.948V	11.950V	15mV	0.125%

(1) 入力変動、負荷変動、温度変動 Line regulation, Load regulation, Temperature drift

15V

1. Line regulation and Load regulation　　Condition　Tbp : 25℃

Io \ Vin	43VDC	72VDC	110VDC	160VDC	Line regulation	
0%	14.988V	14.988V	14.988V	14.987V	1mV	0.007%
50%	14.987V	14.987V	14.987V	14.987V	0mV	0.000%
100%	14.986V	14.986V	14.986V	14.985V	1mV	0.007%
Load	2mV	2mV	2mV	2mV		
regulation	0.013%	0.013%	0.013%	0.013%		

2. Temperature drift　　Conditions　Vin : 110VDC
Io : 100%

Tbp	-40℃	+25℃	+100℃	Temperature stability	
Vo	15.013V	14.986V	14.959V	54mV	0.360%

24V

1. Line regulation and Load regulation　　Condition　Tbp : 25℃

Io \ Vin	43VDC	72VDC	110VDC	160VDC	Line regulation	
0%	24.001V	24.001V	24.001V	24.001V	0mV	0.000%
50%	24.000V	24.000V	24.000V	24.000V	0mV	0.000%
100%	24.000V	24.000V	24.000V	24.000V	0mV	0.000%
Load	1mV	1mV	1mV	1mV		
regulation	0.004%	0.004%	0.004%	0.004%		

2. Temperature drift　　Conditions　Vin : 110VDC
Io : 100%

Tbp	-40℃	+25℃	+100℃	Temperature stability	
Vo	24.030V	24.000V	23.995V	35mV	0.146%

(1) 入力変動、負荷変動、温度変動 Line regulation, Load regulation, Temperature drift

48V

1. Line regulation and Load regulation　　Condition　Tbp : 25℃

Io \ Vin	43VDC	72VDC	110VDC	160VDC	Line regulation	
0%	48.014V	48.013V	48.014V	48.013V	1mV	0.007%
50%	48.012V	48.012V	48.012V	48.012V	0mV	0.000%
100%	48.011V	48.011V	48.011V	48.011V	0mV	0.000%
Load regulation	3mV	2mV	3mV	2mV		
	0.020%	0.013%	0.020%	0.013%		

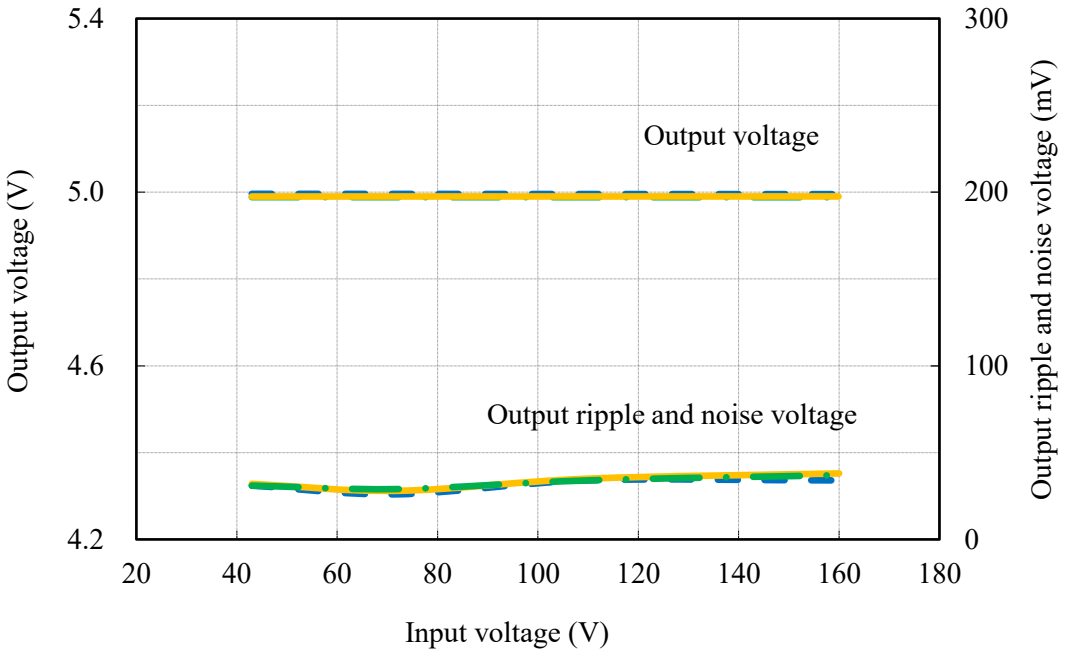
2. Temperature drift　　Conditions　Vin : 110VDC
Io : 100%

Tbp	-40℃	+25℃	+100℃	Temperature stability	
Vo	48.062V	48.011V	48.017V	51mV	0.106%

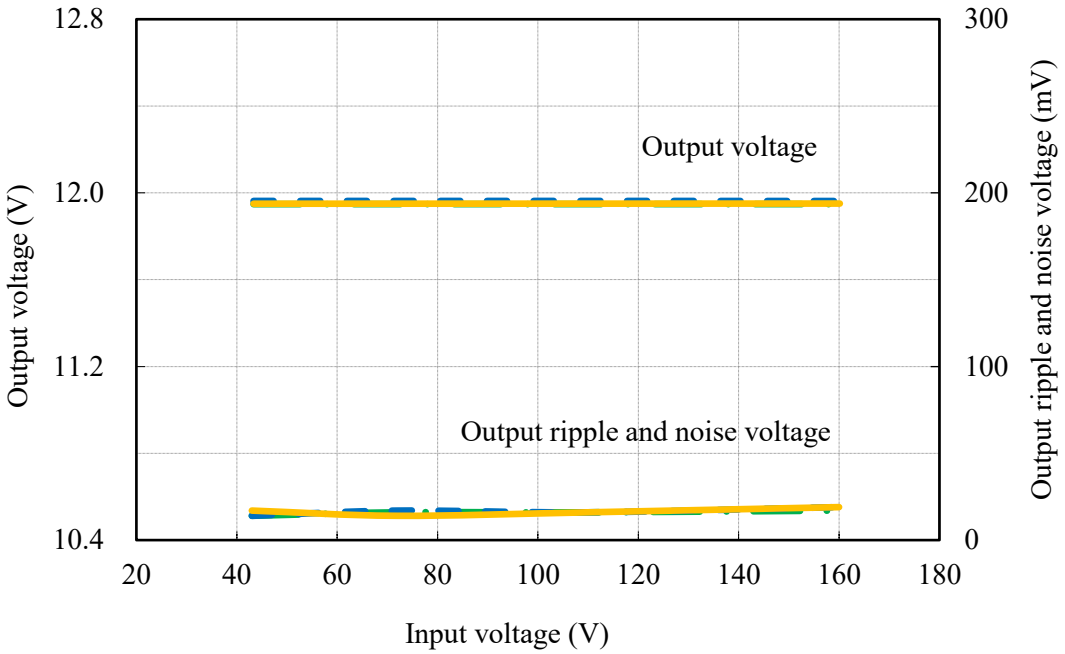
(2) 出力電圧、出力リップル・ノイズ電圧 対 入力電圧
Output voltage and Output ripple and noise voltage vs. Input voltage

Conditions Io : 100 %
Tbp : -40 ℃
: 25 ℃
: 100 ℃

5V



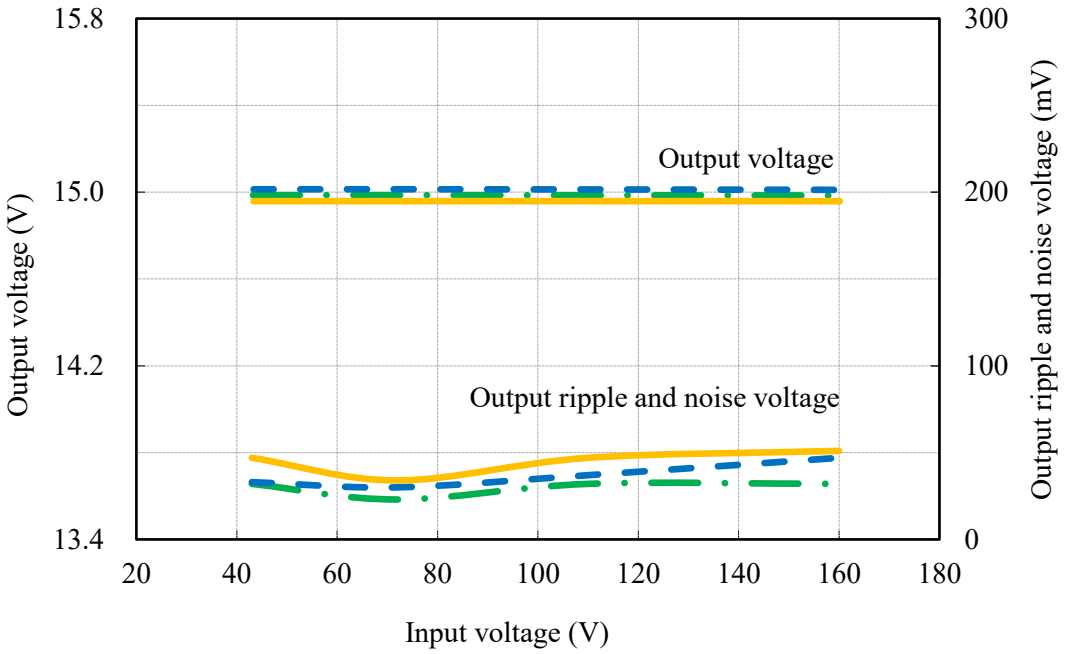
12V



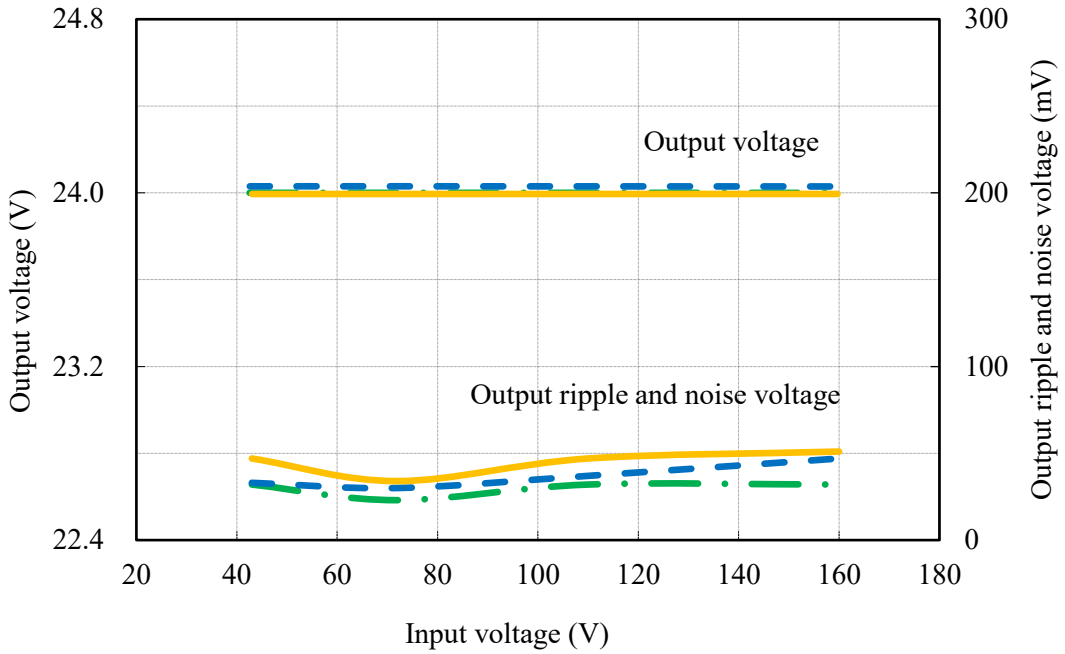
(2) 出力電圧、出力リップル・ノイズ電圧 対 入力電圧
Output voltage and Output ripple and noise voltage vs. Input voltage

Conditions Io : 100 %
Tbp : -40 ℃
: 25 ℃
: 100 ℃

15V



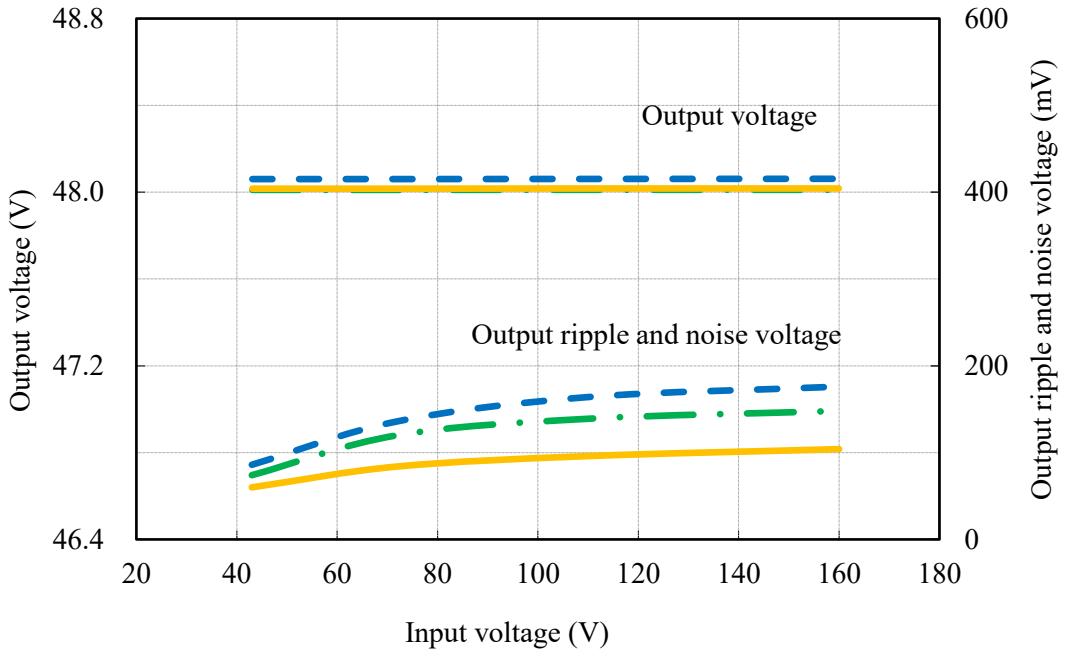
24V



(2) 出力電圧、出力リップル・ノイズ電圧 対 入力電圧
Output voltage and Output ripple and noise voltage vs. Input voltage

Conditions Io : 100 %
Tbp : -40 ℃
: 25 ℃
: 100 ℃

48V

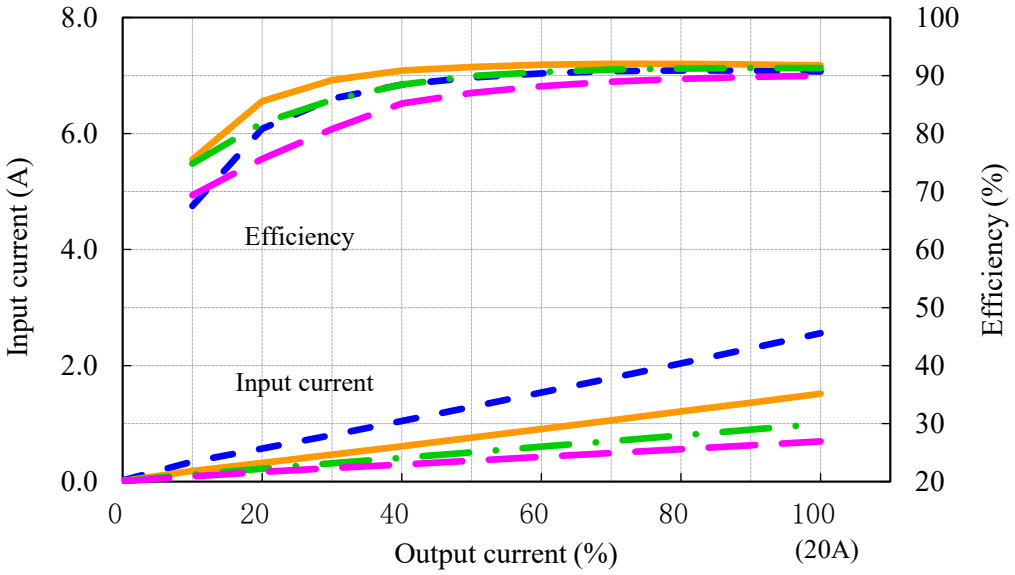


(3) 入力電流、効率 対 出力電流

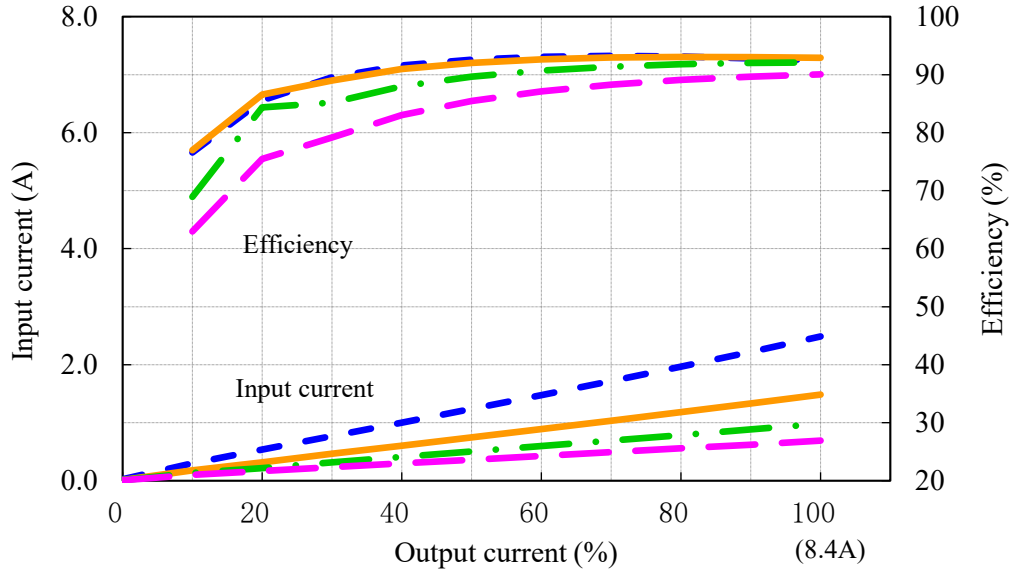
Input current and Efficiency vs. Output current

Conditions Vin : 43 VDC
: 72 VDC
: 110 VDC
: 160 VDC
Tbp : 25 ℃

5V



12V



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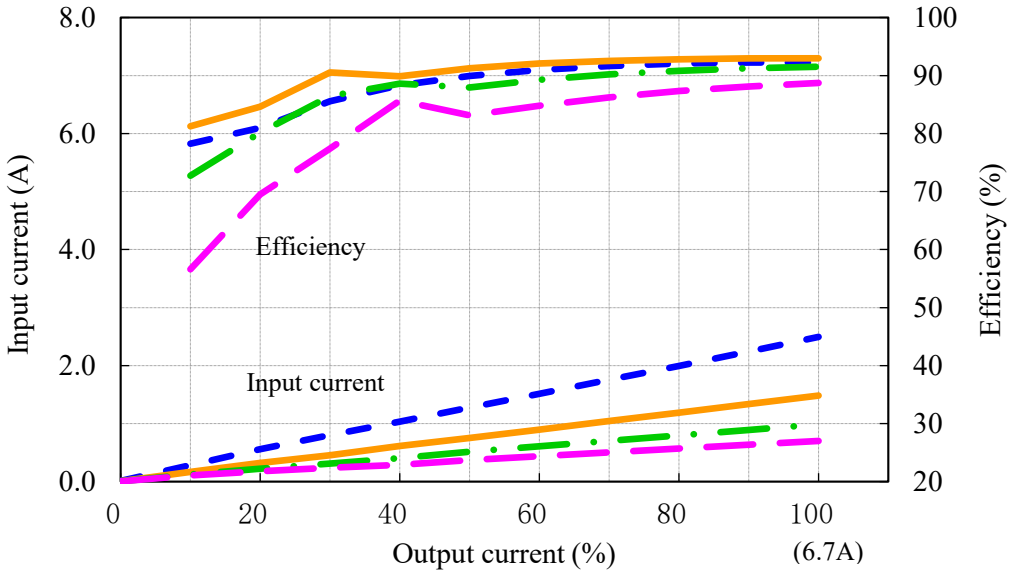
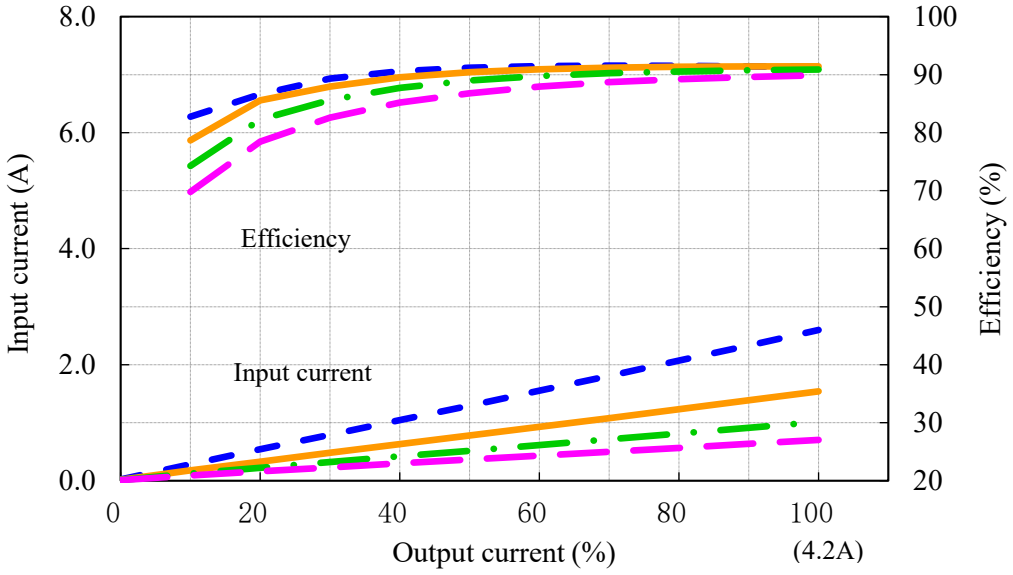
15V



24V



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: 110 VDC
: 160 VDC
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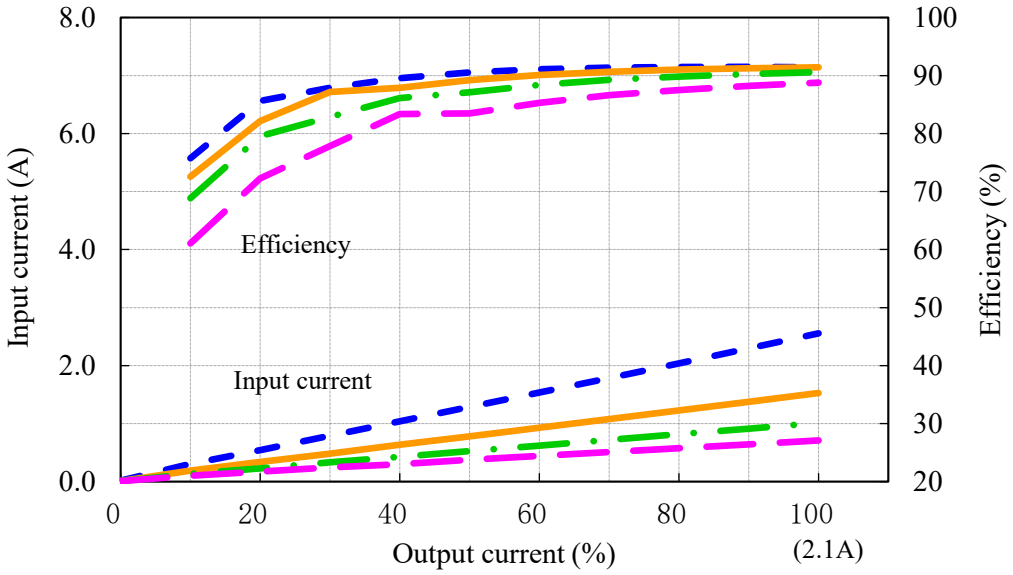
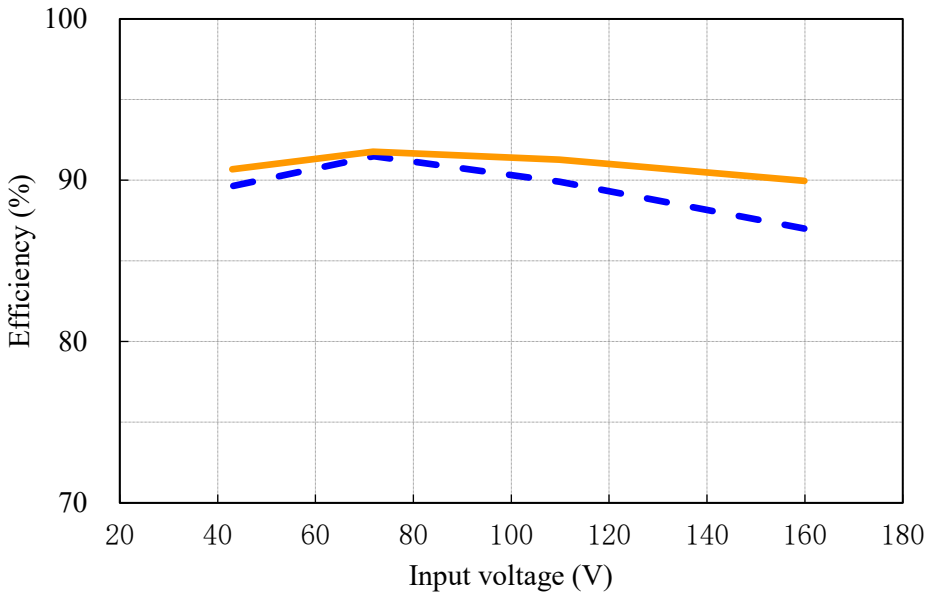
48V



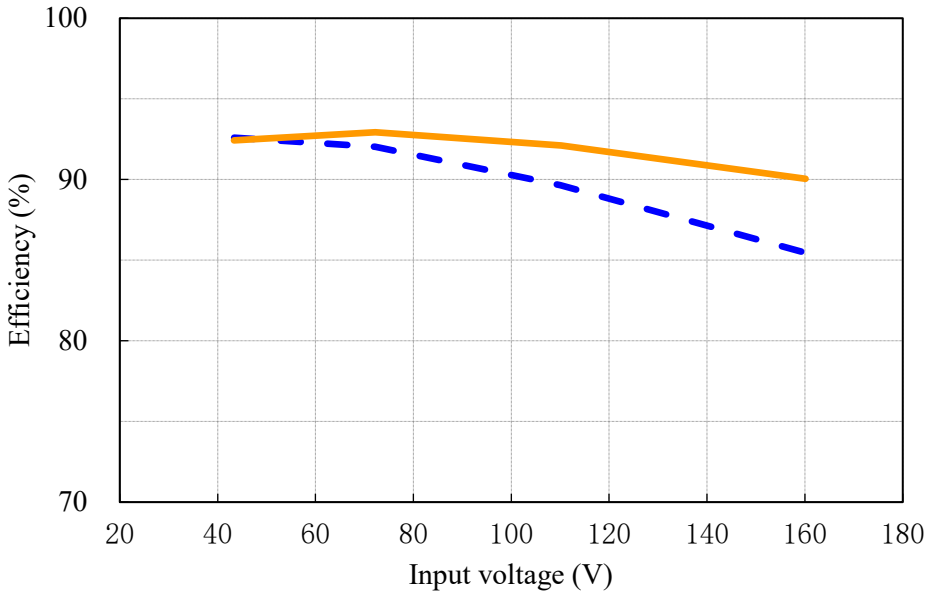
(4) 効率 対 入力電圧
Efficiency vs. Input voltage

Conditions Io : 50 % - - - - -
: 100 % ——
Tbp : 25 ℃

5V



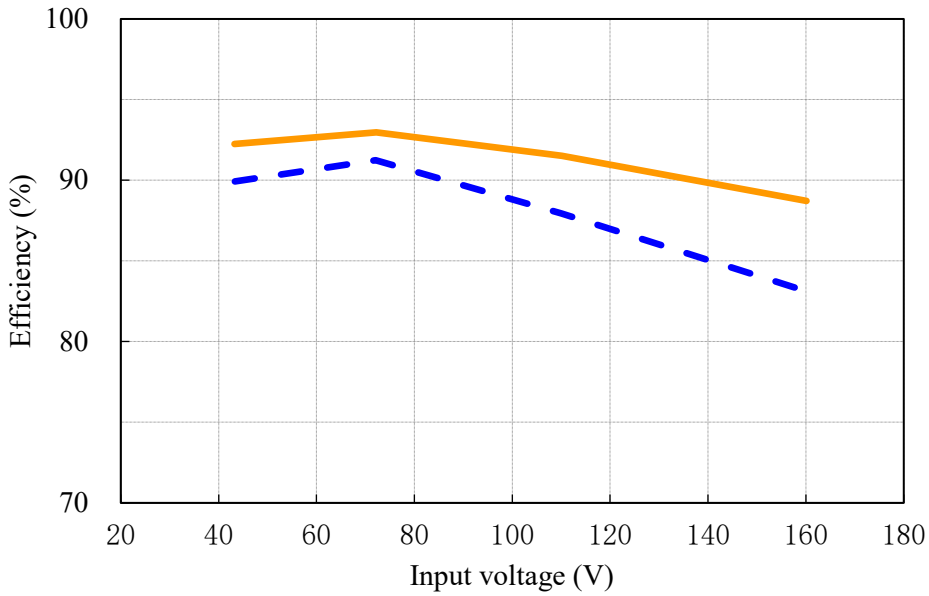
12V



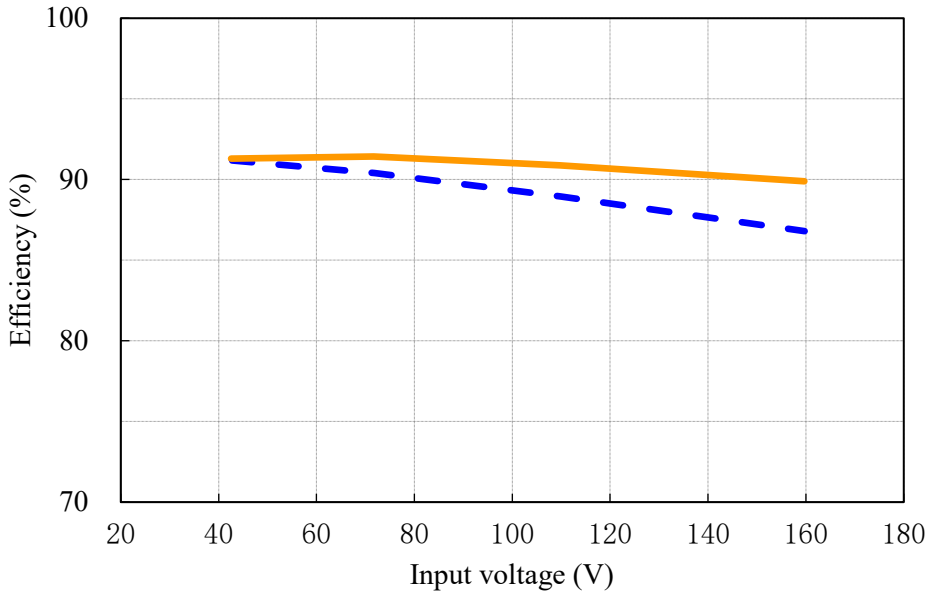
(4) 効率 対 入力電圧
Efficiency vs. Input voltage

Conditions Io : 50 % ----
: 100 % ——
Tbp : 25 ℃

15V



24V



(4) 効率 対 入力電圧
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Conditions Io : 50 % - - - - -
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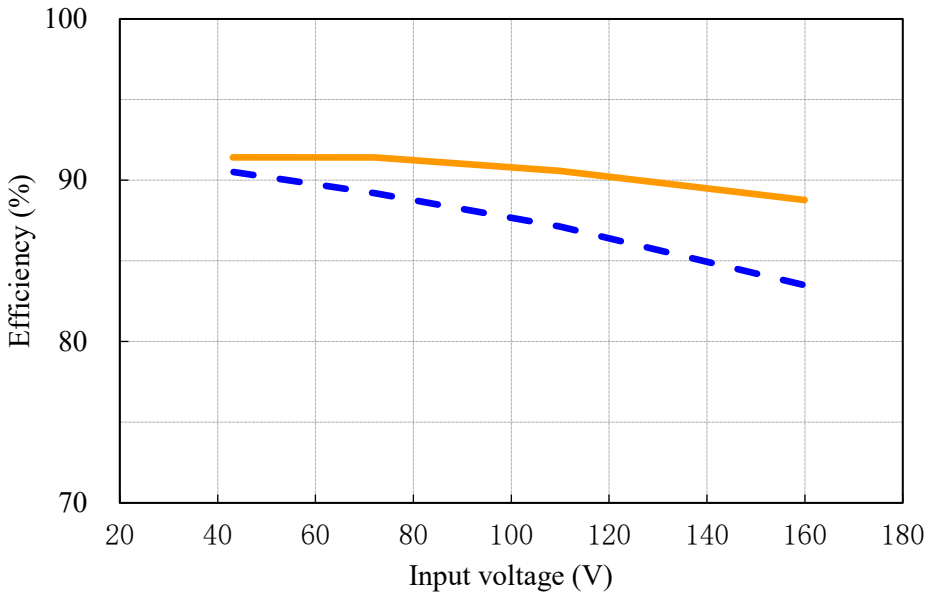
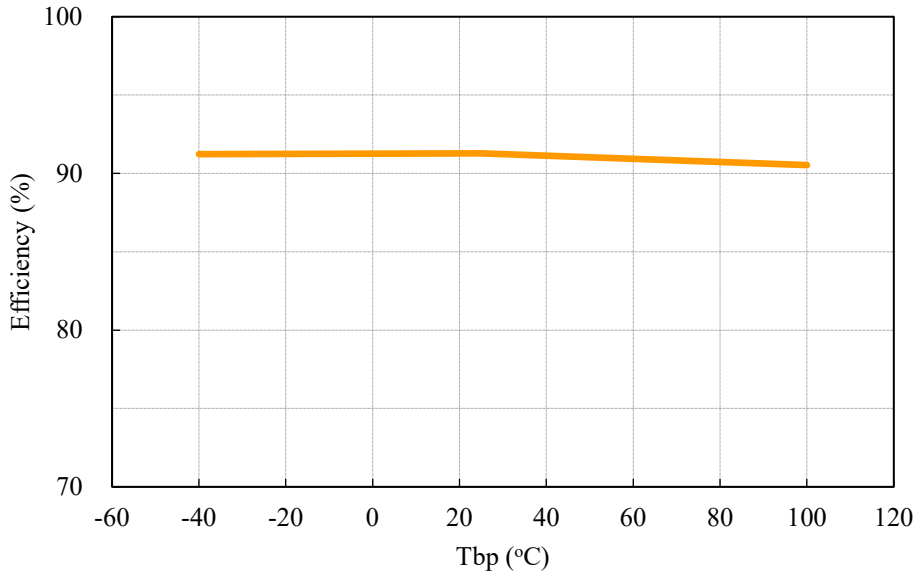
48V



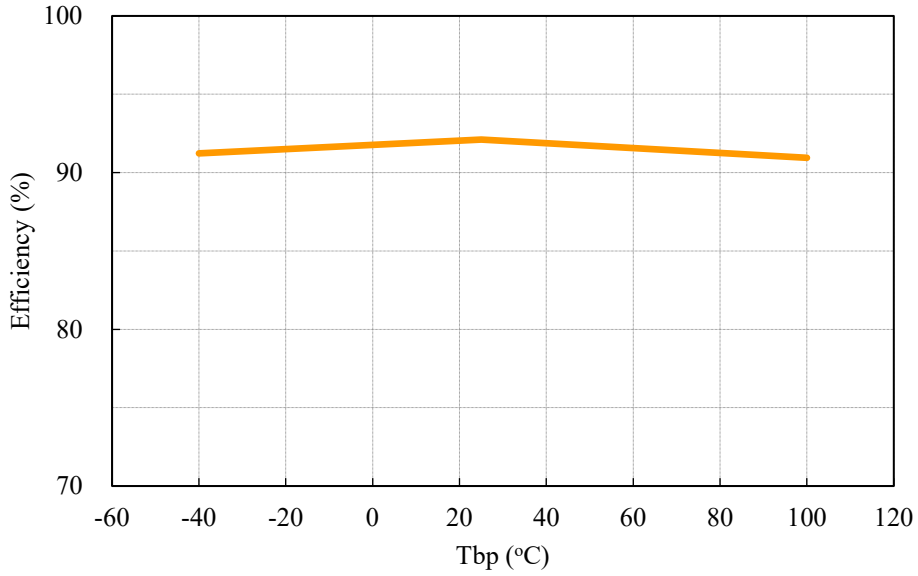
(5) 効率 対 ベースプレート温度
Efficiency vs. Base-plate temperature

Conditions Vin : 110 VDC
Io : 100 %

5V



12V



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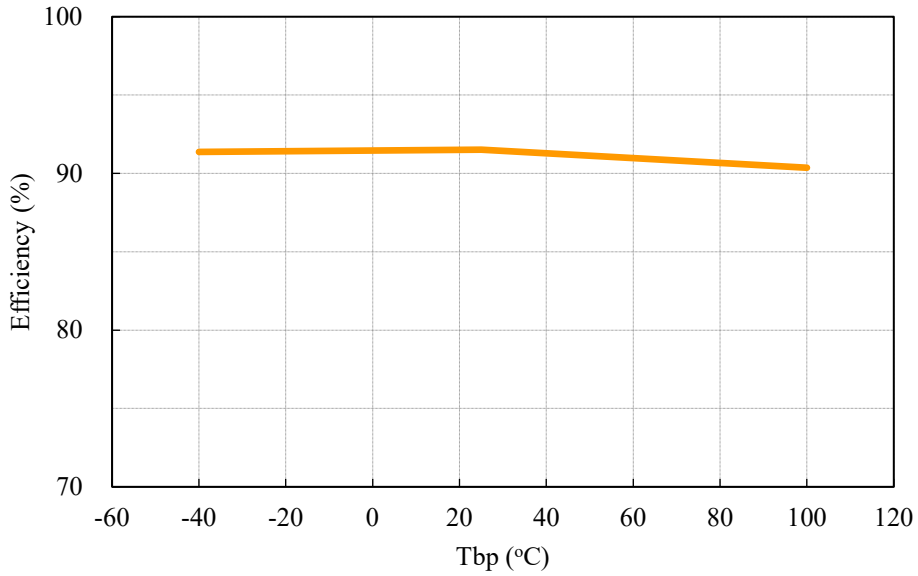
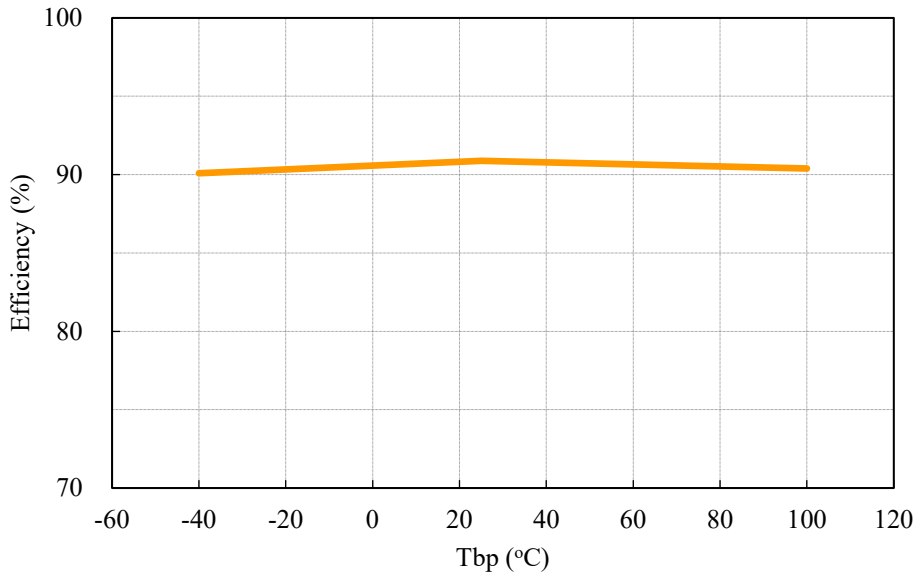
Io : 100 %

15V



24V



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Conditions Vin : 110 VDC
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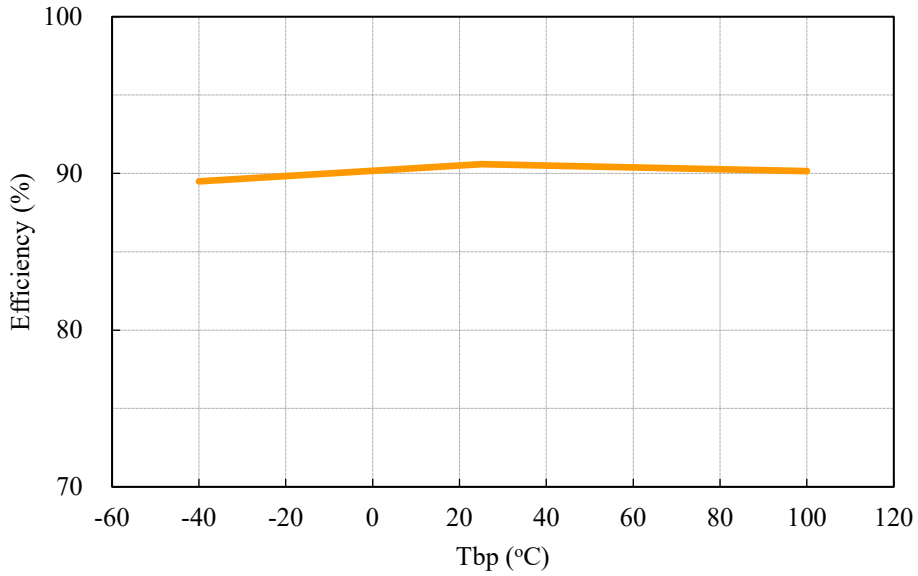
48V



(6) 起動、停止電圧特性
Start and Stop voltage characteristics

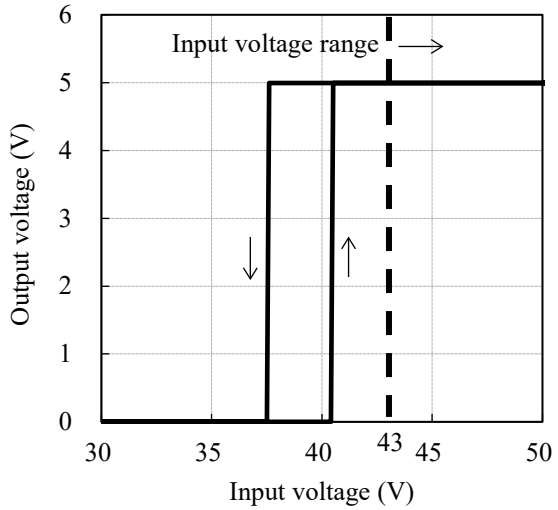
出力電圧 対 入力電圧
Output voltage vs. Input voltage

Conditions Io : 100 %
Tbp : 25 °C

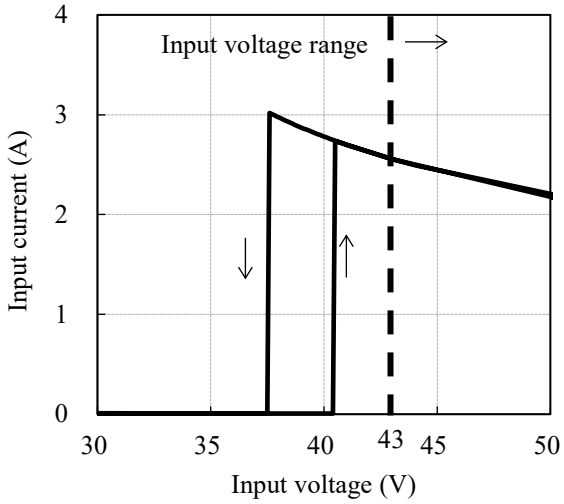
入力電流 対 入力電圧
Input current vs. Input voltage

Conditions Io : 100 %
Tbp : 25 °C

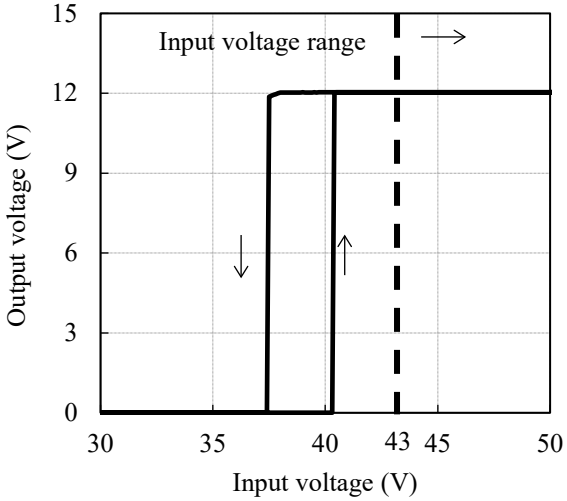
5V



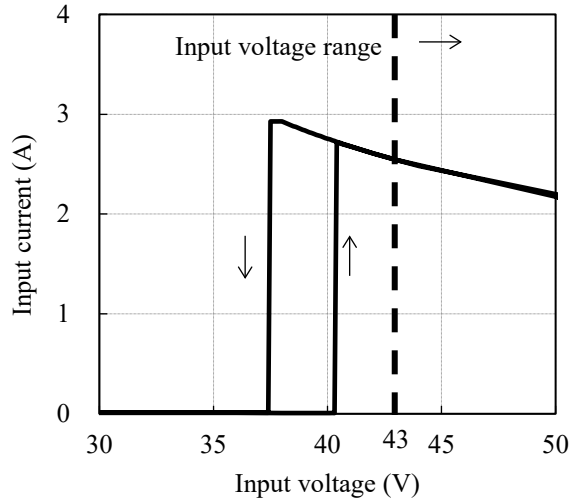
5V



12V



12V



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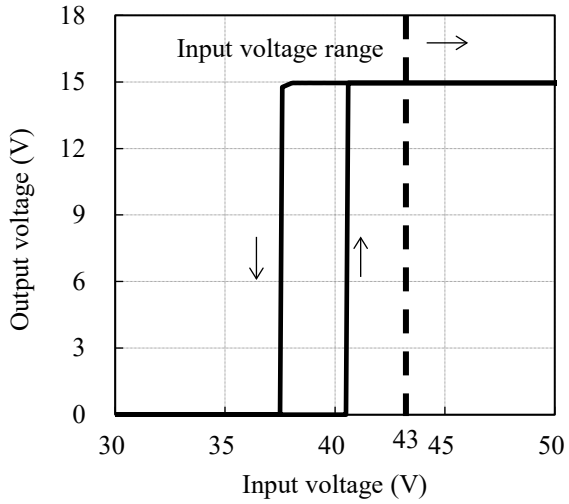
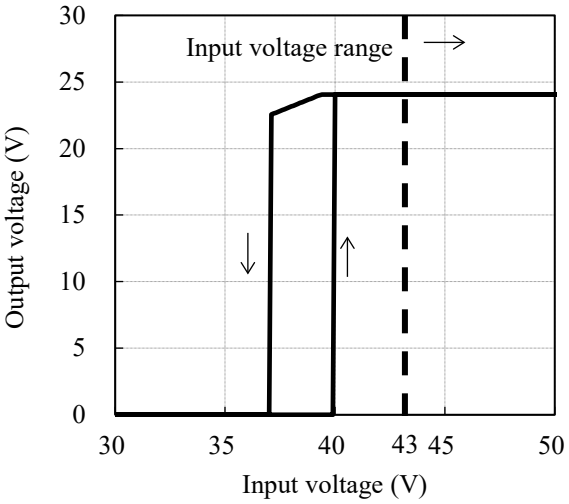


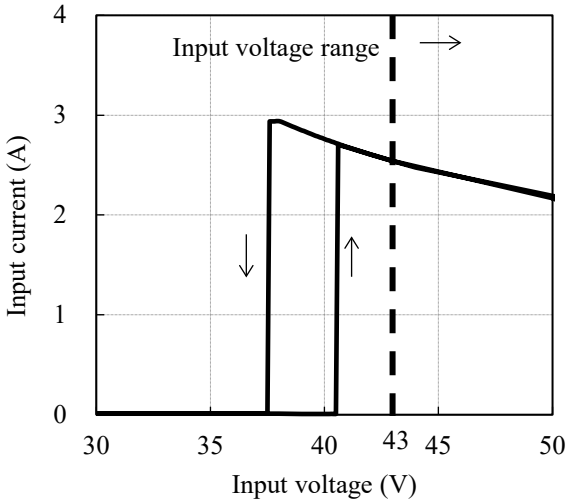
24V



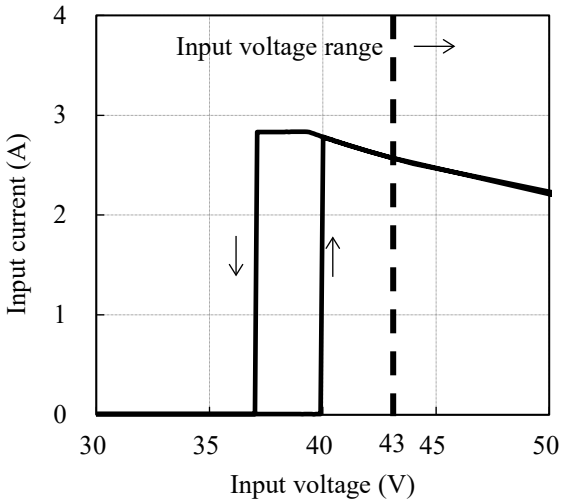
入力電流 対 入力電圧
Input current vs. Input voltage

Conditions Io : 100 %
Tbp : 25 °C

15V



24V

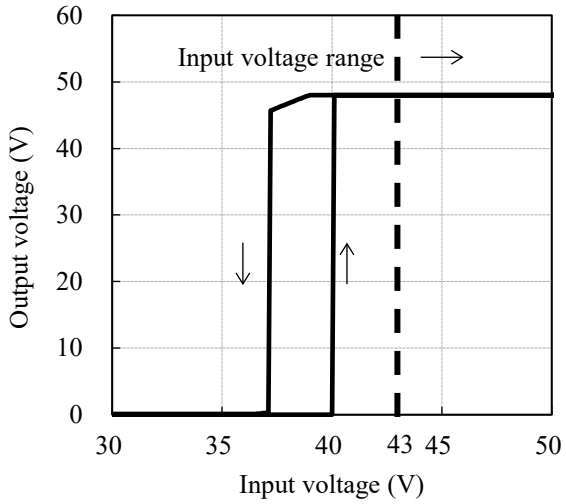


(6) 起動、停止電圧特性
Start and Stop voltage characteristics

出力電圧 対 入力電圧
Output voltage vs. Input voltage

Conditions Io : 100 %
Tbp : 25 °C

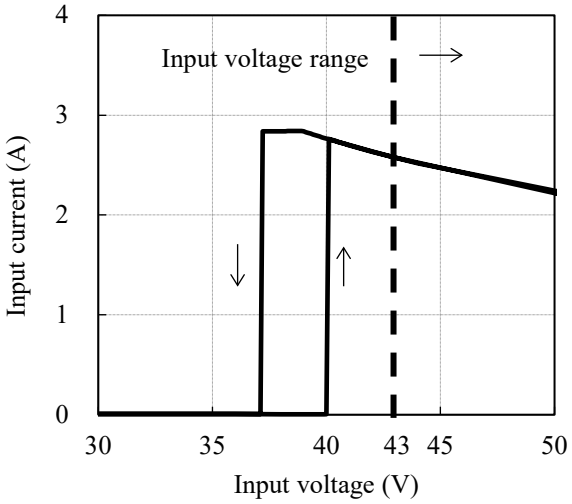
48V



入力電流 対 入力電圧
Input current vs. Input voltage

Conditions Io : 100 %
Tbp : 25 °C

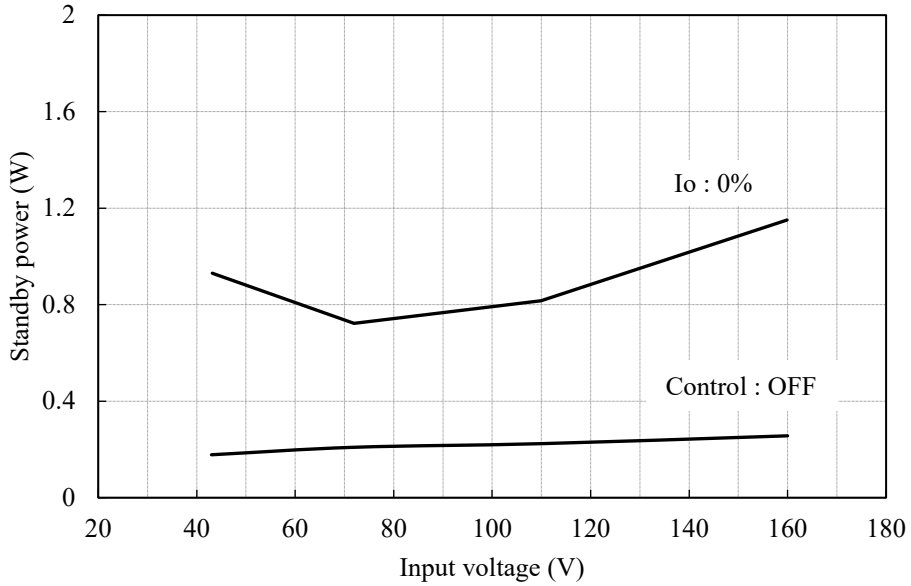
48V



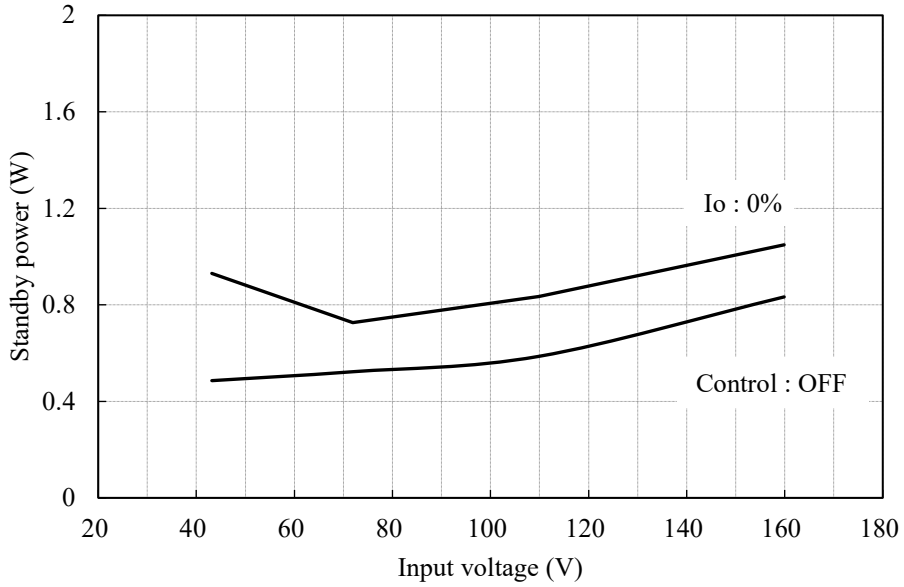
2.2 待機電力特性

Standby power characteristics　　Conditions　Tbp: 25℃

5V



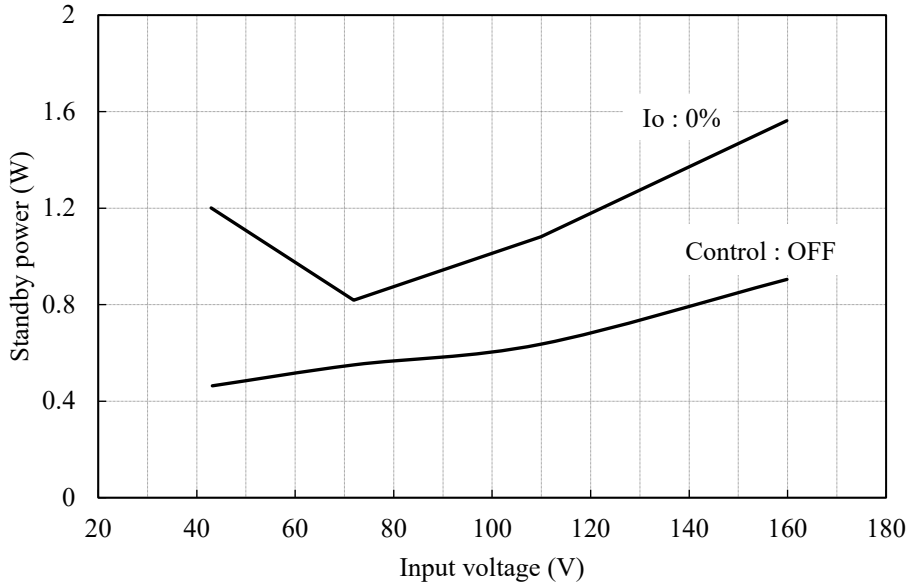
12V



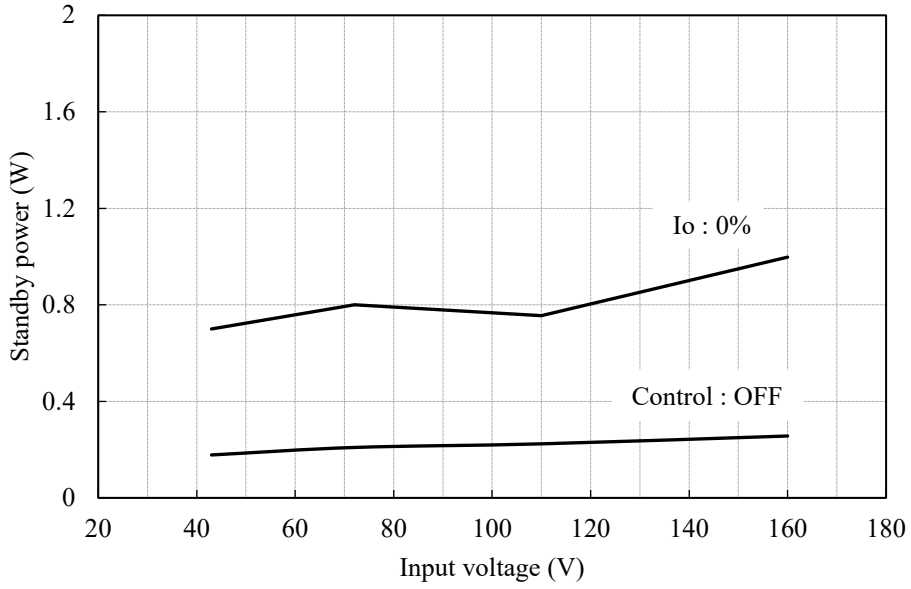
2.2 待機電力特性

Standby power characteristics　　Conditions　Tbp: 25℃

15V



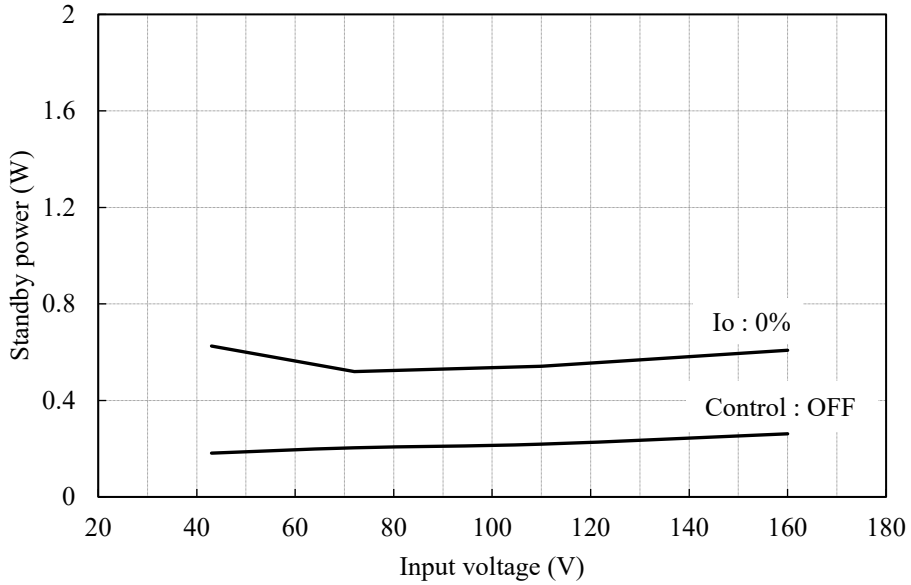
24V



2.2 待機電力特性

Standby power characteristics　　Conditions　Tbp: 25℃

48V

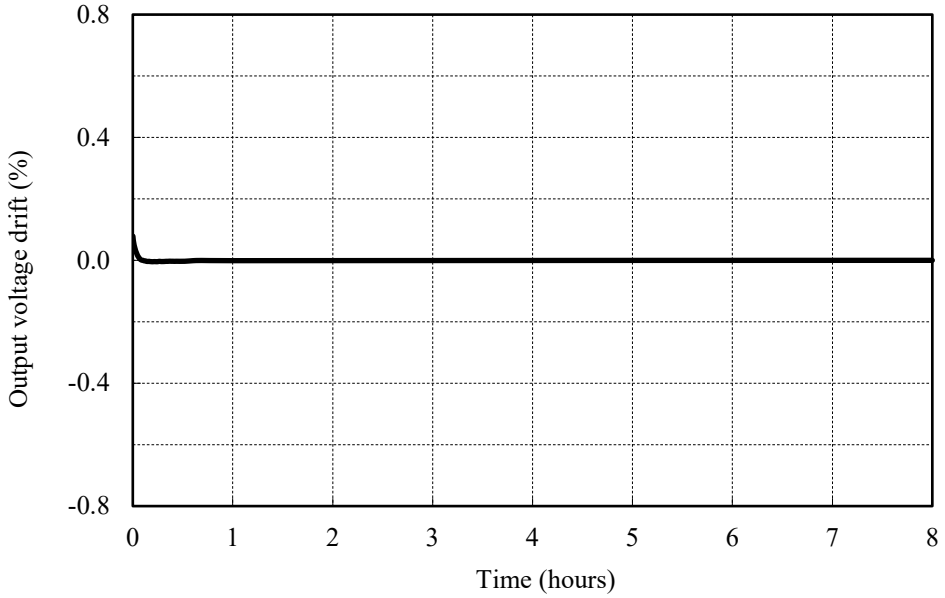


2.3 通電ドリフト特性

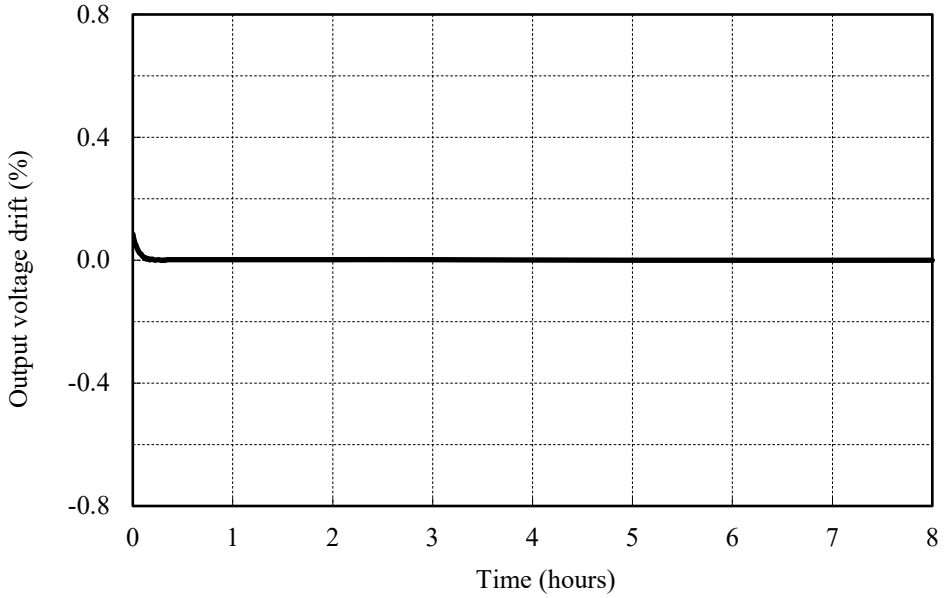
Warm up voltage drift characteristics

Conditions Vin : 110VDC
Io : 100%
Ta : 25℃

5V



12V

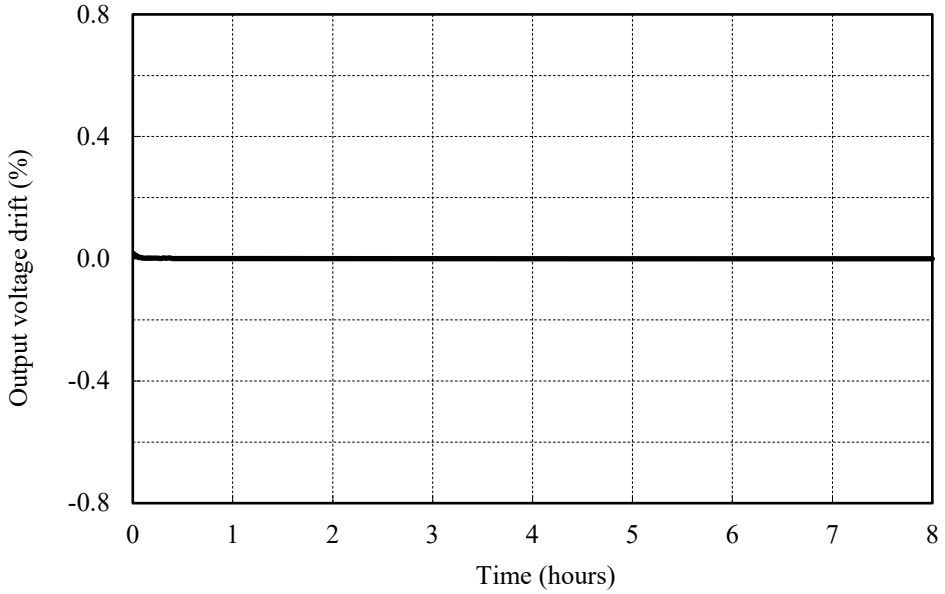


2.3 通電ドリフト特性

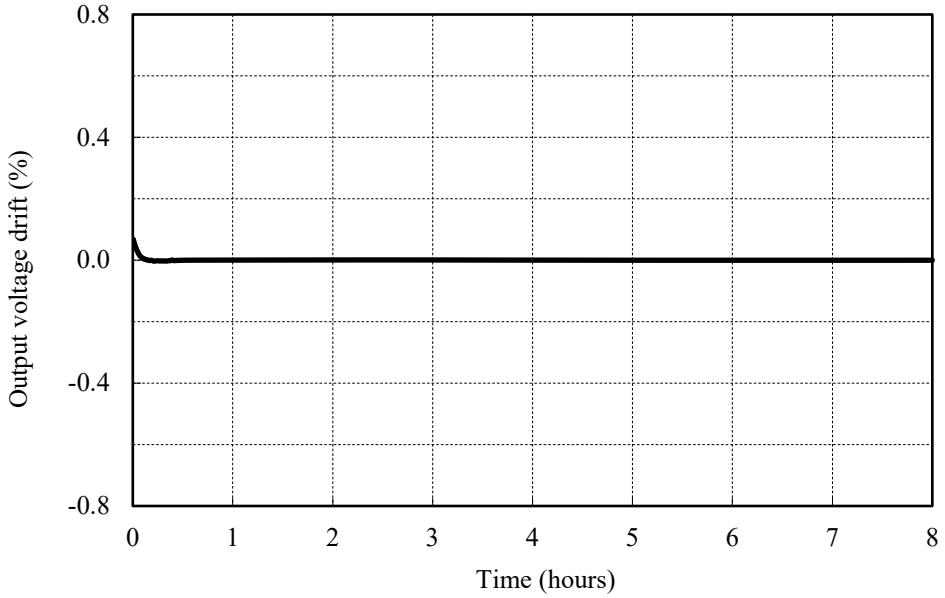
Warm up voltage drift characteristics

Conditions Vin : 110VDC
Io : 100%
Ta : 25℃

15V



24V

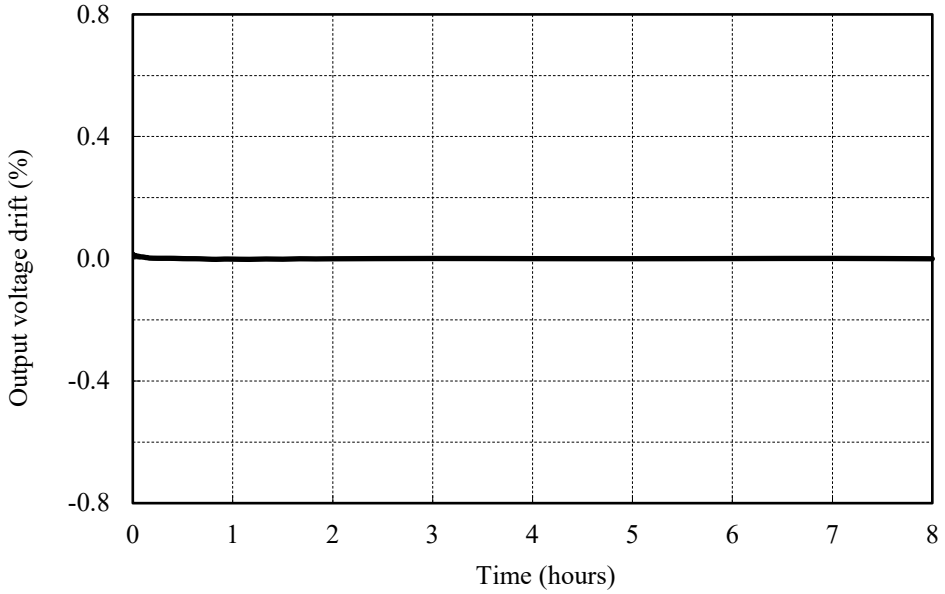


2.3 通電ドリフト特性

Warm up voltage drift characteristics

Conditions Vin : 110VDC
Io : 100%
Ta : 25℃

48V



2.4 過電流保護特性
Over current protection (OCP) characteristics

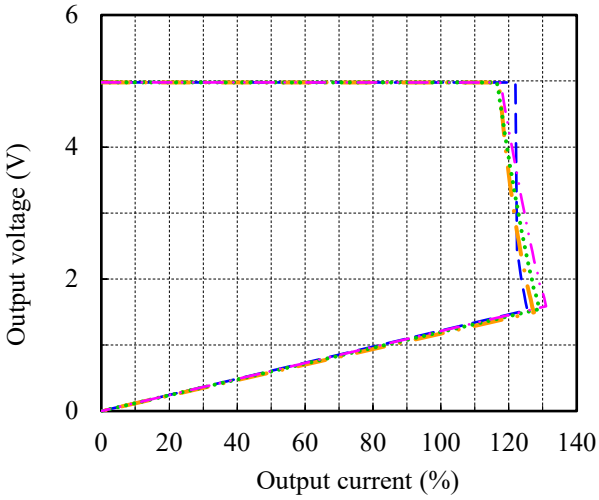
入力電圧依存性
Input voltage dependence

Conditions Vin : 43 VDC
: 72 VDC
: 110 VDC
: 160 VDC
Tbp : 25 ℃

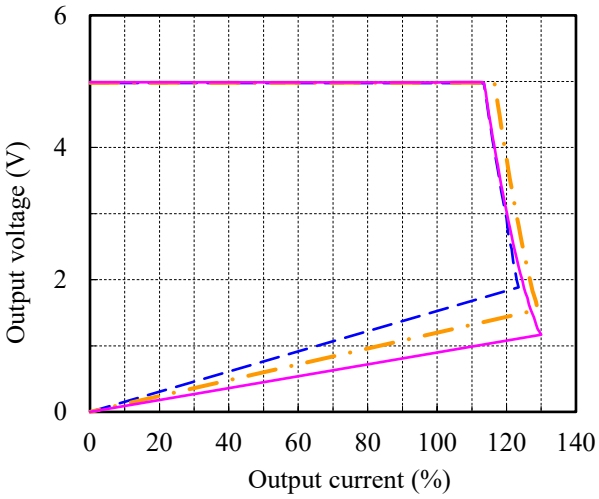
ベースプレート温度依存性
Base-plate temperature dependence

Conditions Vin : 110 VDC
Tbp : -40 ℃
: 25 ℃
: 100 ℃

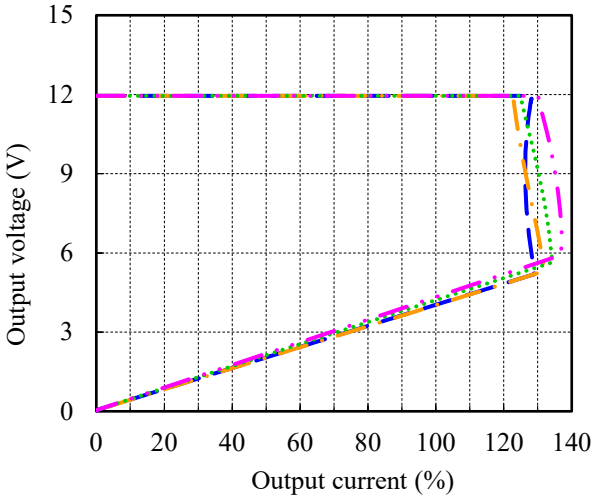
5V



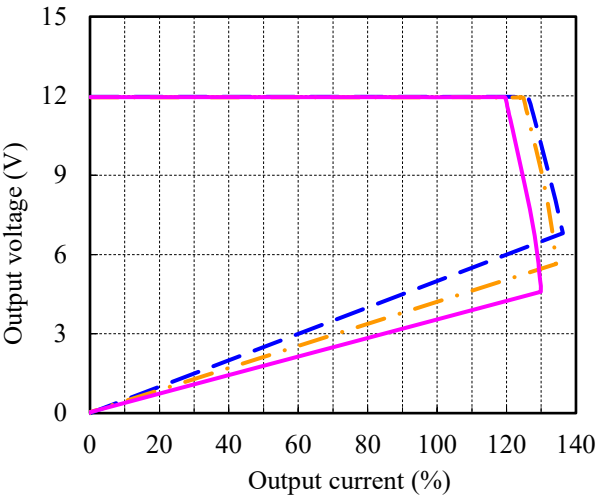
5V



12V



12V



2.4 過電流保護特性
Over current protection (OCP) characteristics

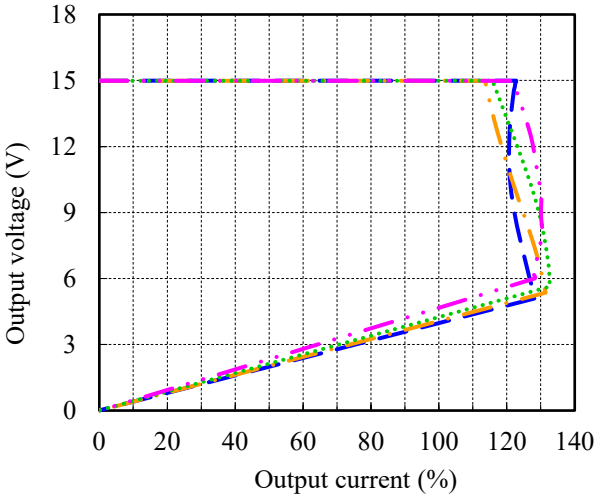
入力電圧依存性
Input voltage dependence

Conditions Vin : 43 VDC
: 72 VDC
: 110 VDC
: 160 VDC
Tbp : 25 ℃

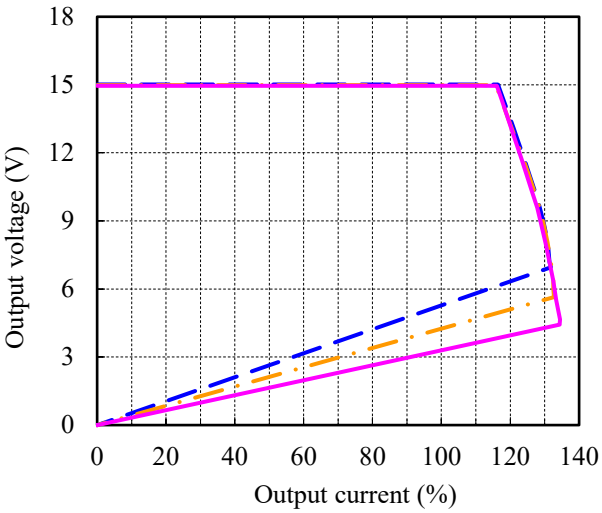
ベースプレート温度依存性
Base-plate temperature dependence

Conditions Vin : 110 VDC
Tbp : -40 ℃
: 25 ℃
: 100 ℃

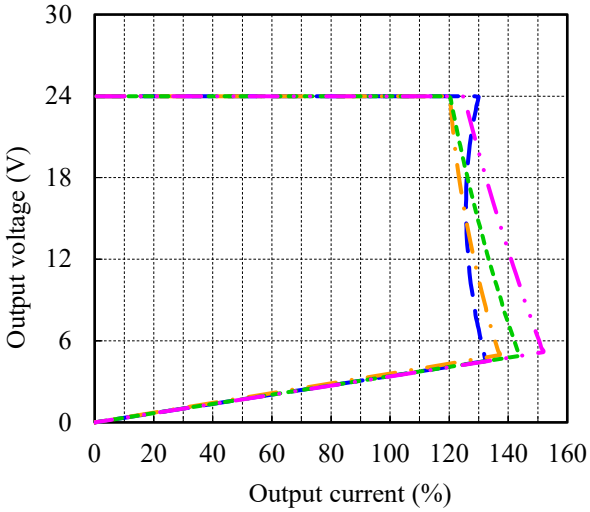
15V



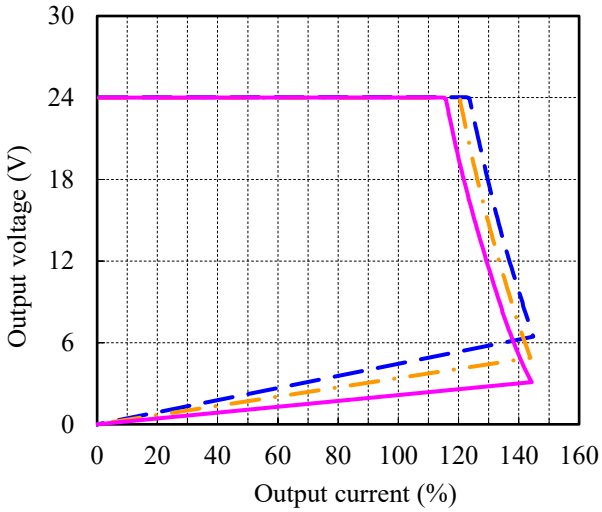
15V



24V



24V

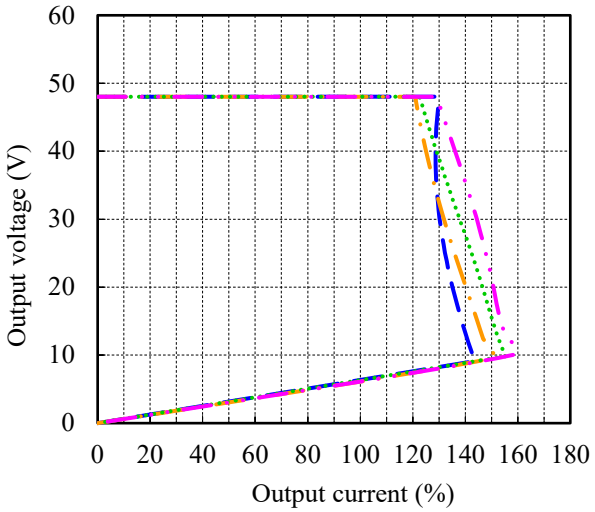


2.4 過電流保護特性
Over current protection (OCP) characteristics

入力電圧依存性
Input voltage dependence

Conditions Vin : 43 VDC
: 72 VDC
: 110 VDC
: 160 VDC
Tbp : 25 ℃

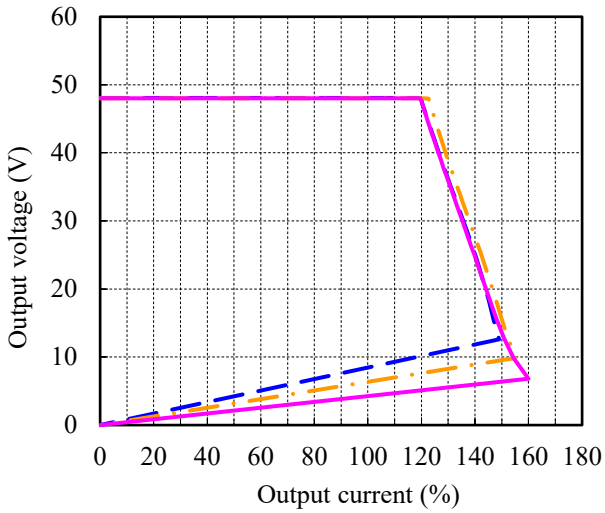
48V



ベースプレート温度依存性
Base-plate temperature dependence

Conditions Vin : 110 VDC
Tbp : -40 ℃
: 25 ℃
: 100 ℃

48V

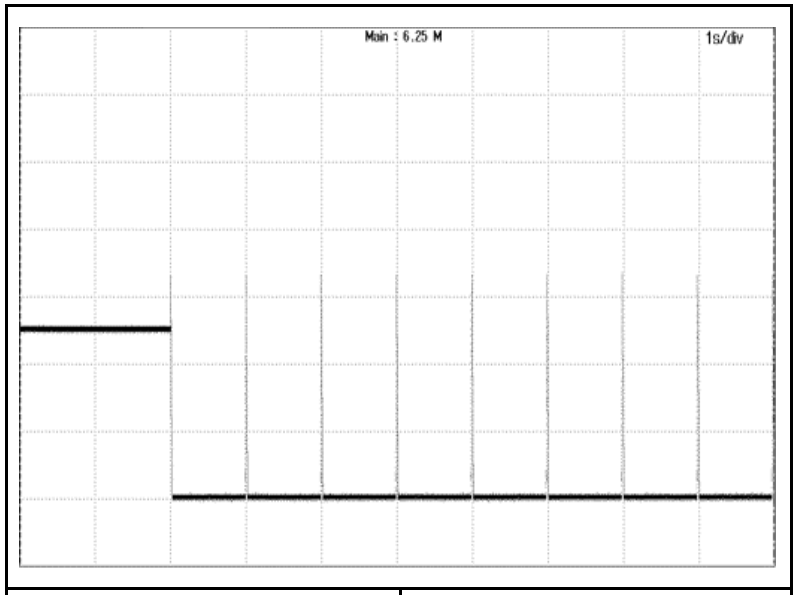


2.5 過電圧保護特性

Over voltage protection (OVP) characteristics

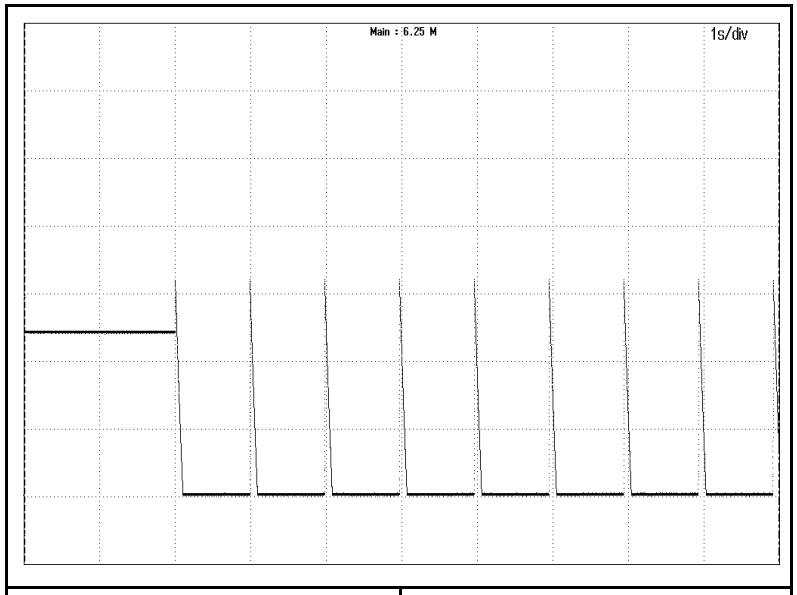
Conditions Vin : 110 VDC
Io : 1%
Tbp : 25 ℃

5V



2V/DIV	1s/DIV

12V



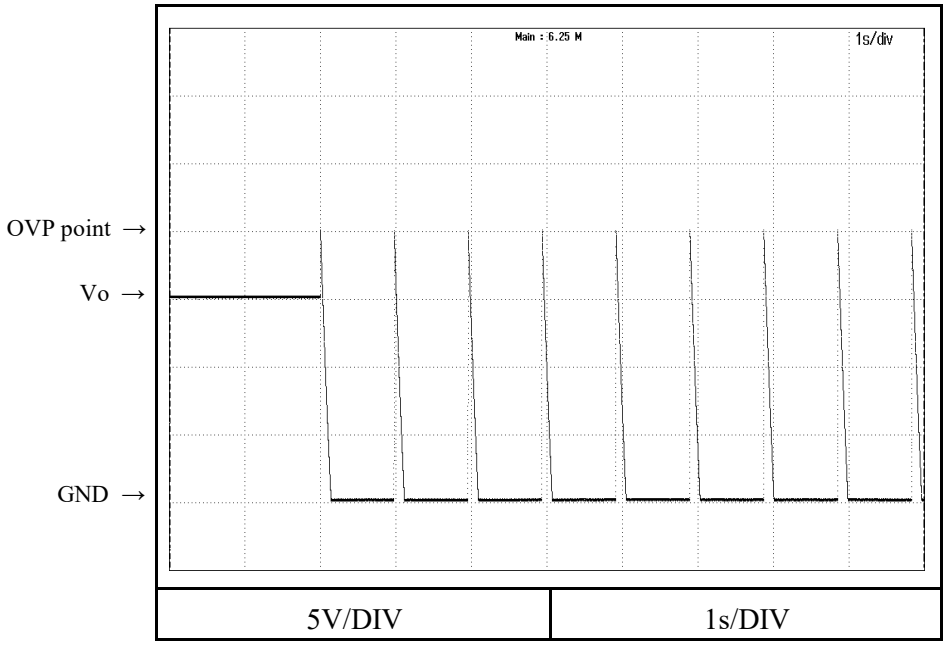
5V/DIV	1s/DIV

2.5 過電圧保護特性

Over voltage protection (OVP) characteristics

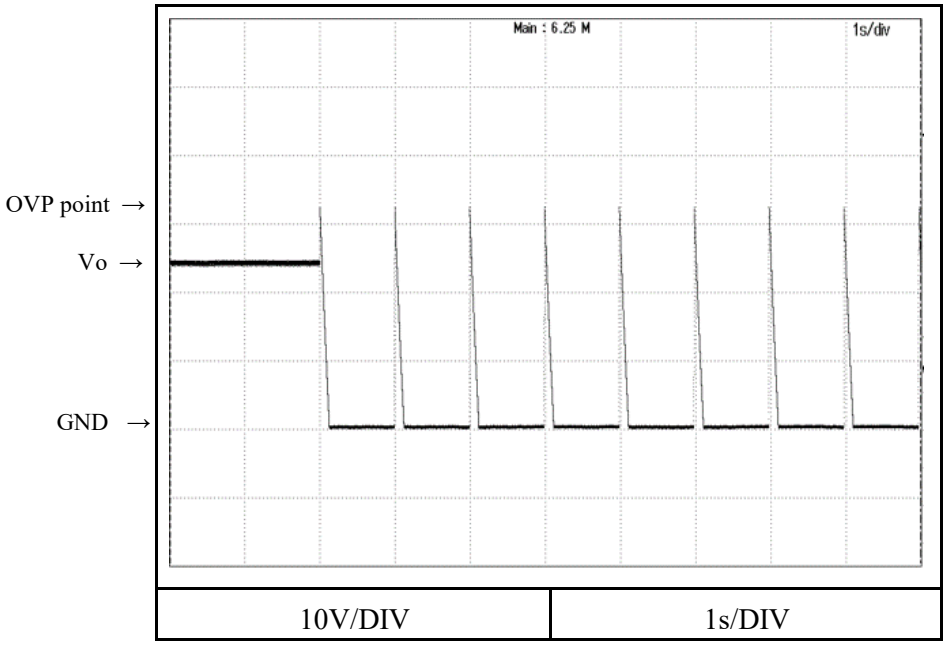
Conditions Vin : 110 VDC
Io : 1%
Tbp : 25 ℃

15V



5V/DIV	1s/DIV

24V



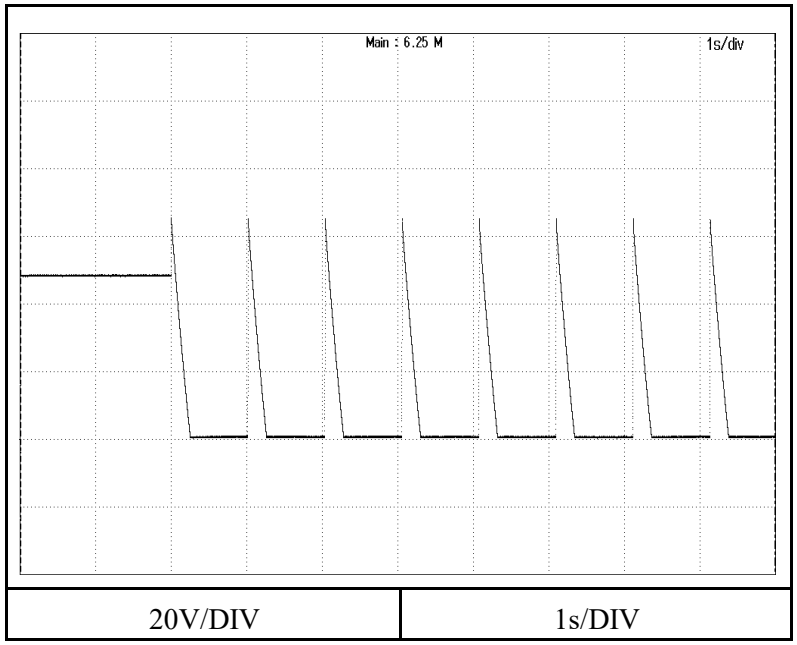
10V/DIV	1s/DIV

2.5 過電圧保護特性

Over voltage protection (OVP) characteristics

Conditions Vin : 110 VDC
Io : 1%
Tbp : 25 ℃

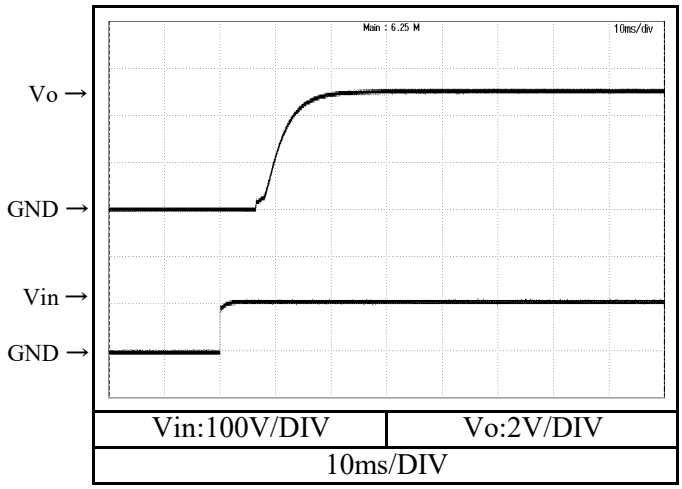
48V



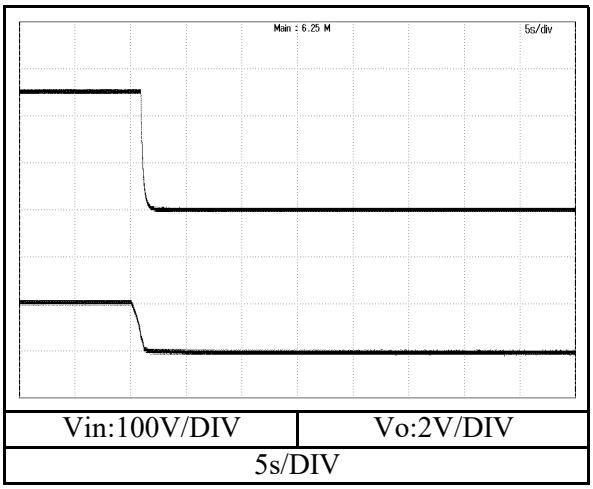
2.6 出力立ち上がり、立ち下がり特性
Output rise and fall characteristics

Conditions Vin : 110 VDC
Io : 0 %
Tbp : 25℃

5V

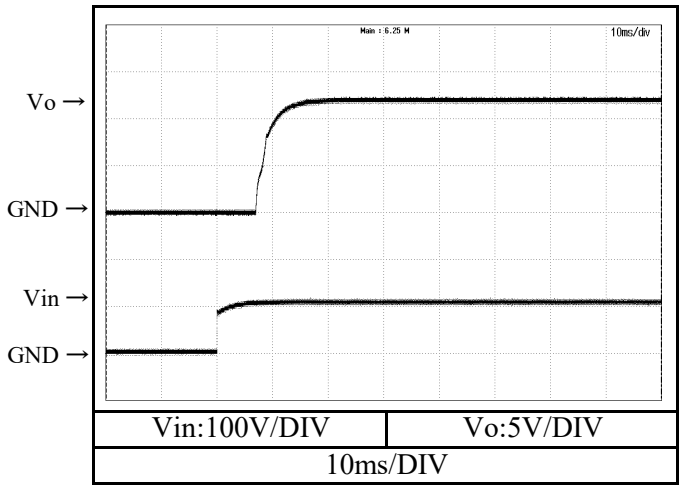


Vin:100V/DIV	Vo:2V/DIV
10ms/DIV	

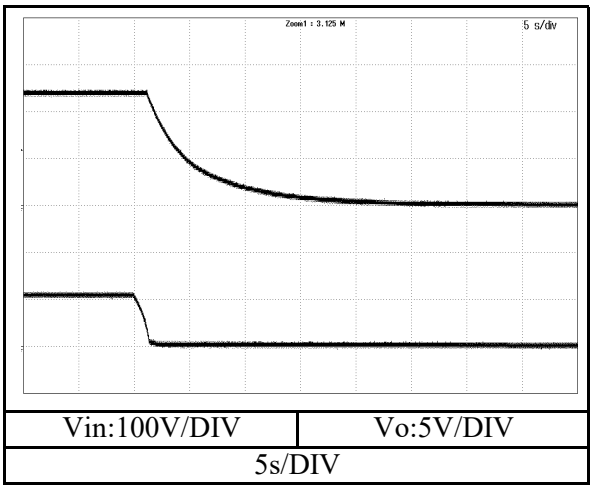


Vin:100V/DIV	Vo:2V/DIV
5s/DIV	

12V



Vin:100V/DIV	Vo:5V/DIV
10ms/DIV	

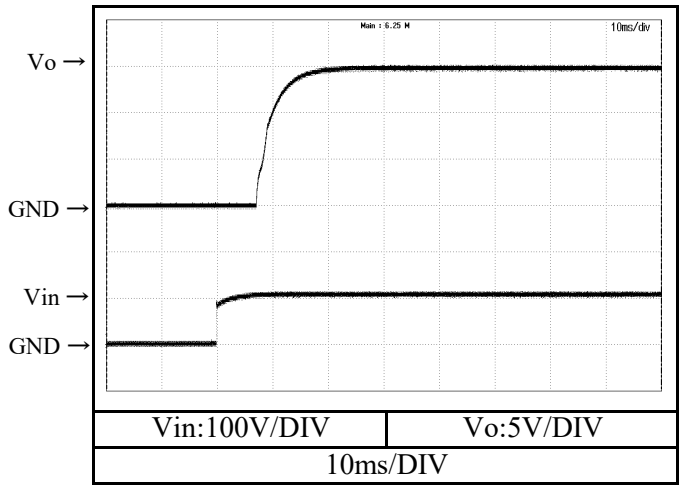


Vin:100V/DIV	Vo:5V/DIV
5s/DIV	

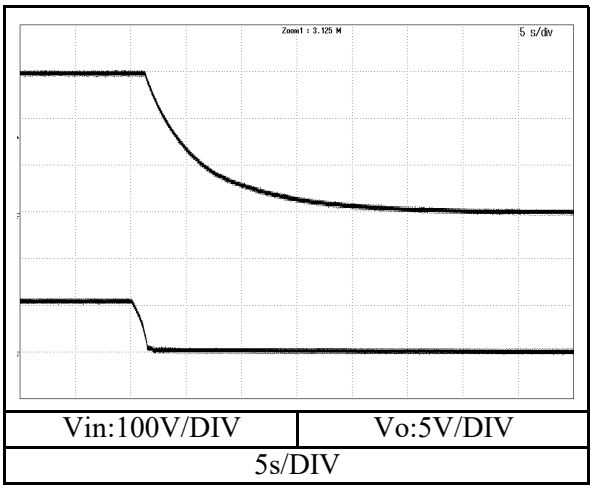
2.6 出力立ち上がり、立ち下がり特性
Output rise and fall characteristics

Conditions Vin : 110 VDC
Io : 0 %
Tbp : 25℃

15V

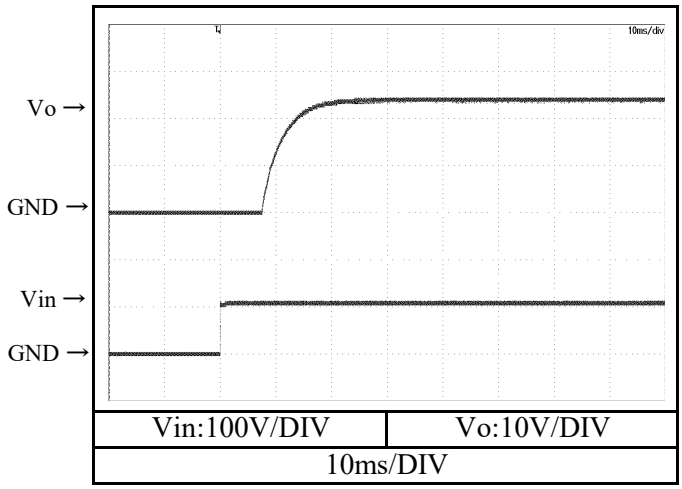


Vin:100V/DIV	Vo:5V/DIV
10ms/DIV	

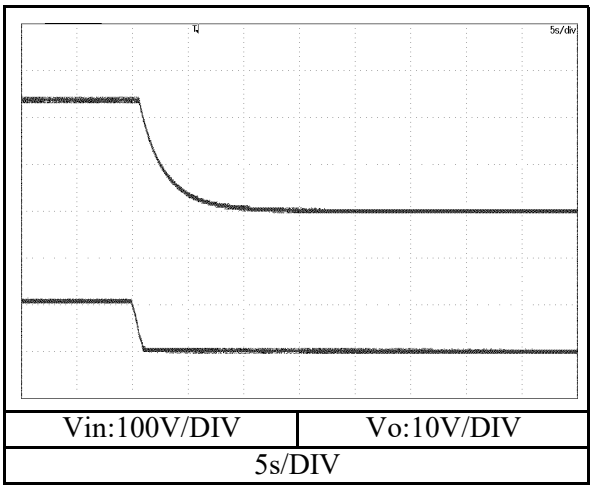


Vin:100V/DIV	Vo:5V/DIV
5s/DIV	

24V



Vin:100V/DIV	Vo:10V/DIV
10ms/DIV	

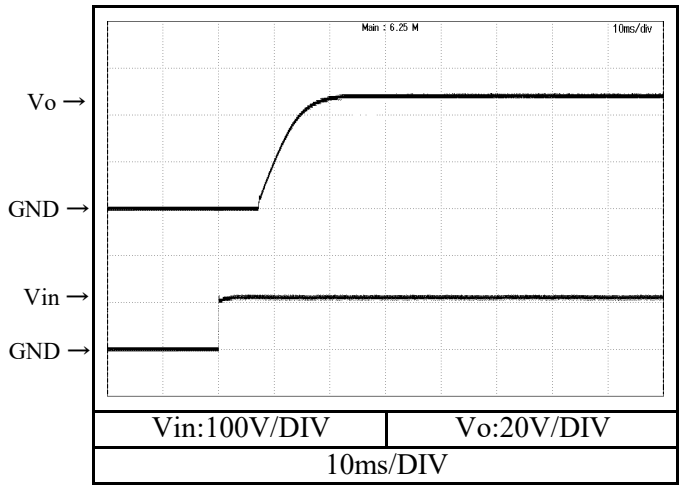


Vin:100V/DIV	Vo:10V/DIV
5s/DIV	

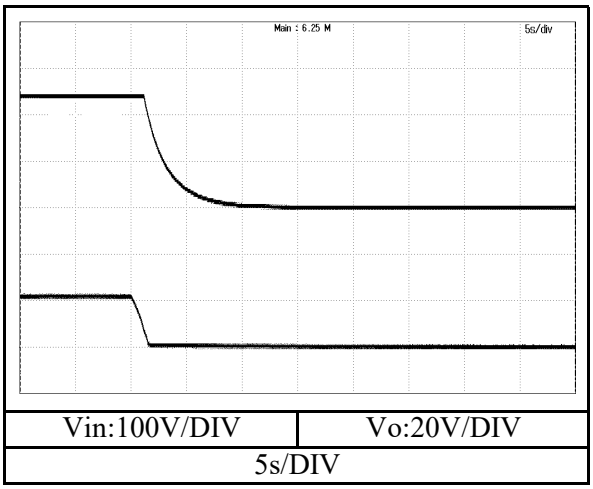
2.6 出力立ち上がり、立ち下がり特性
Output rise and fall characteristics

Conditions Vin : 110 VDC
Io : 0 %
Tbp : 25℃

48V



Vin:100V/DIV	Vo:20V/DIV
10ms/DIV	

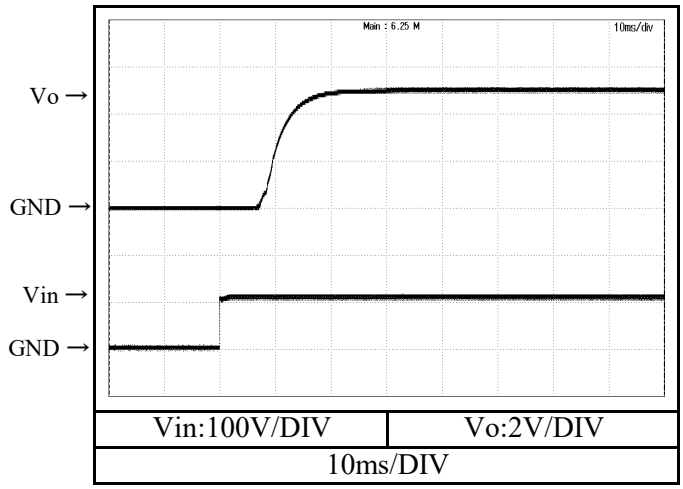


Vin:100V/DIV	Vo:20V/DIV
5s/DIV	

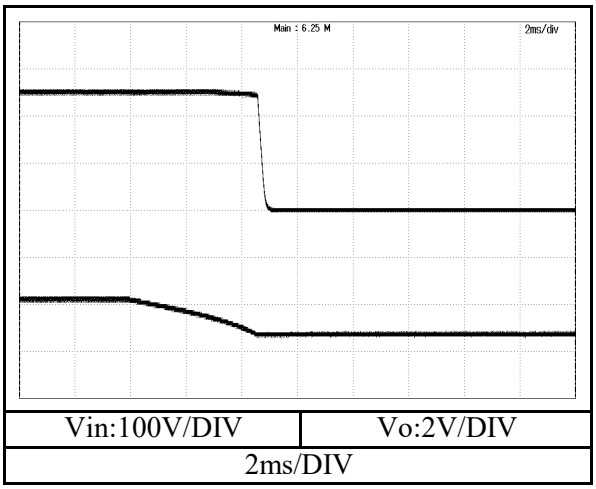
2.6 出力立ち上がり、立ち下がり特性
Output rise and fall characteristics

Conditions Vin : 110 VDC
Io : 100 %
Tbp : 25℃

5V

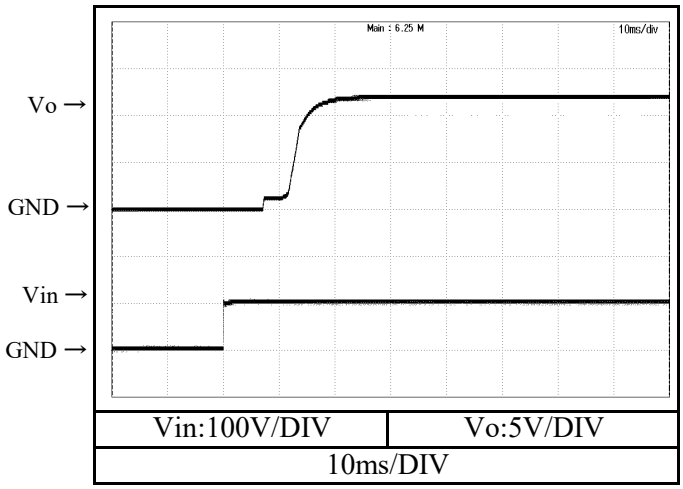


Vin:100V/DIV	Vo:2V/DIV
10ms/DIV	

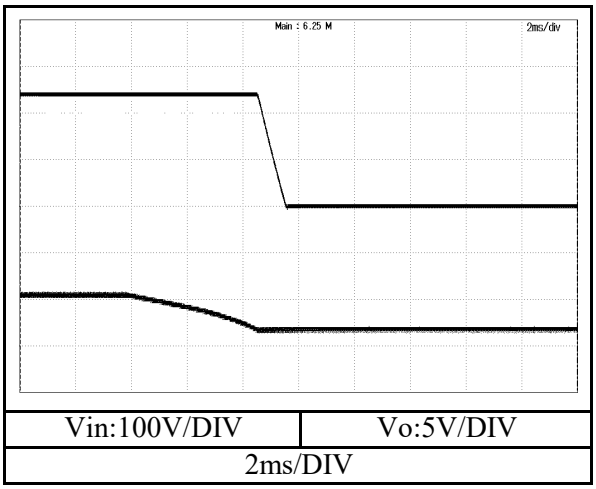


Vin:100V/DIV	Vo:2V/DIV
2ms/DIV	

12V



Vin:100V/DIV	Vo:5V/DIV
10ms/DIV	

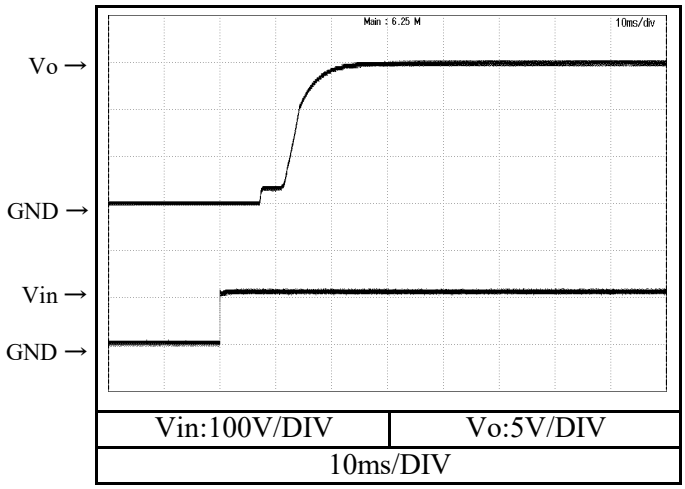


Vin:100V/DIV	Vo:5V/DIV
2ms/DIV	

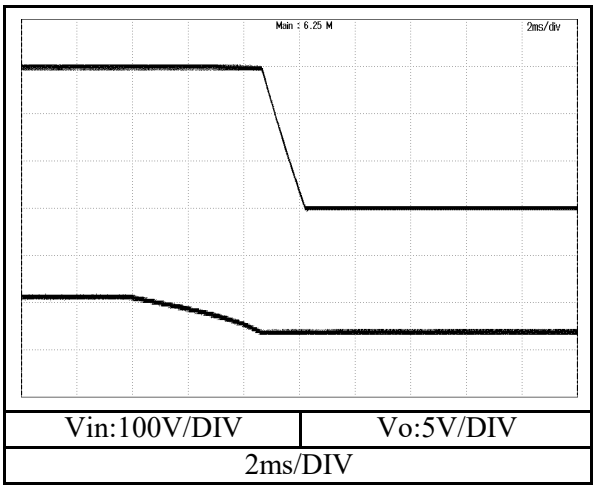
2.6 出力立ち上がり、立ち下がり特性
Output rise and fall characteristics

Conditions Vin : 110 VDC
Io : 100 %
Tbp : 25℃

15V

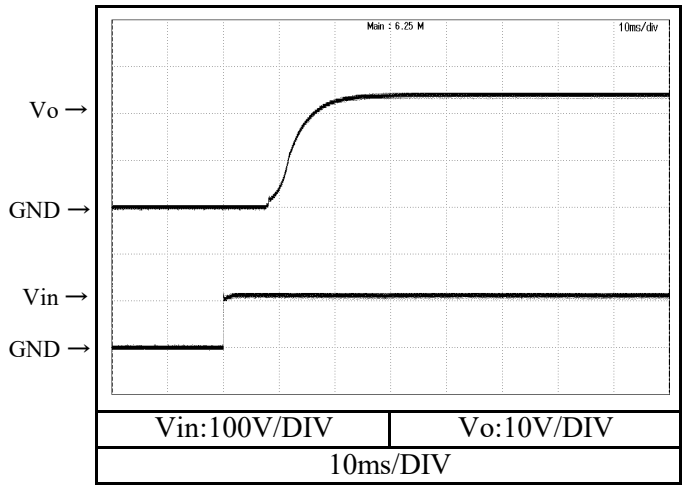


Vin:100V/DIV	Vo:5V/DIV
10ms/DIV	

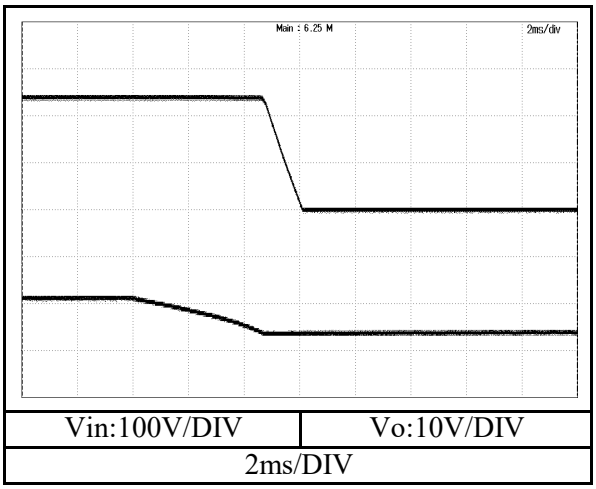


Vin:100V/DIV	Vo:5V/DIV
2ms/DIV	

24V



Vin:100V/DIV	Vo:10V/DIV
10ms/DIV	

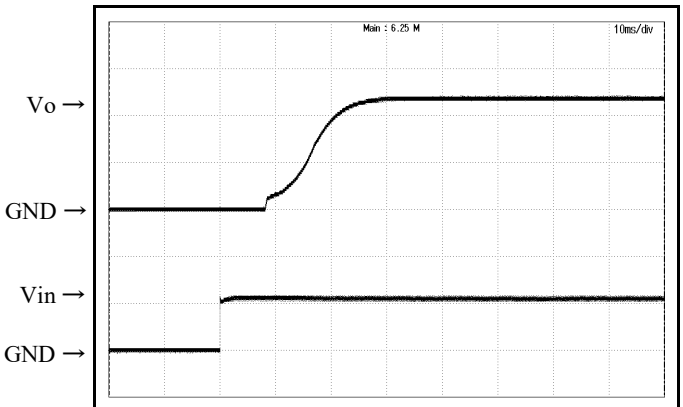


Vin:100V/DIV	Vo:10V/DIV
2ms/DIV	

2.6 出力立ち上がり、立ち下がり特性
Output rise and fall characteristics

Conditions Vin : 110 VDC
Io : 100 %
Tbp : 25℃

48V



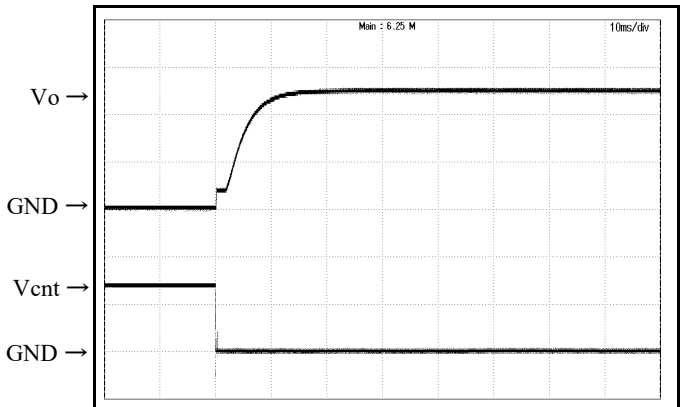
Vin:100V/DIV	Vo:20V/DIV
10ms/DIV	

Vin:100V/DIV	Vo:20V/DIV
2ms/DIV	

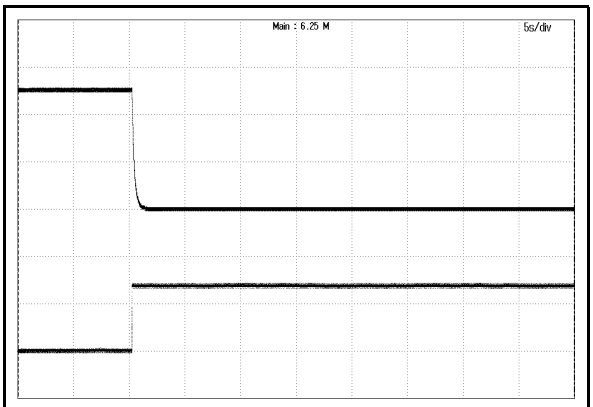
2.6 出力立ち上がり、立ち下がり特性（ON/OFFコントロール時）

Output rise and fall characteristics with ON/OFF CONTROL　　Conditions　　Vin : 110 VDC
Io : 0 %
Tbp : 25℃

5V

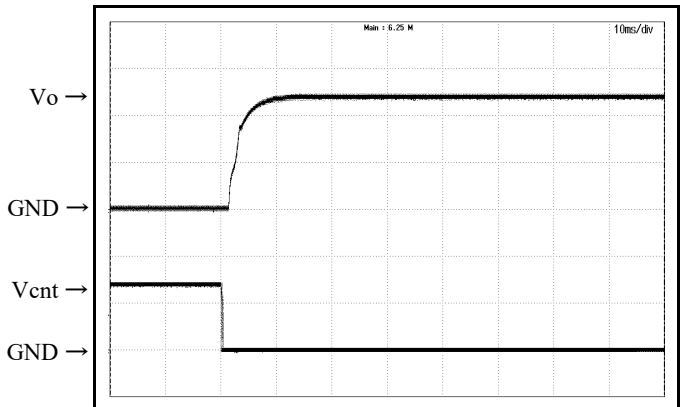


Vcnt:5V/DIV	Vo:2V/DIV
10ms/DIV	

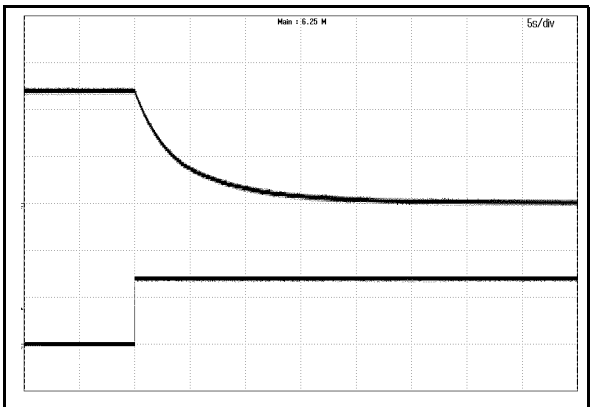


Vcnt:5V/DIV	Vo:2V/DIV
5s/DIV	

12V



Vcnt:5V/DIV	Vo:5V/DIV
10ms/DIV	

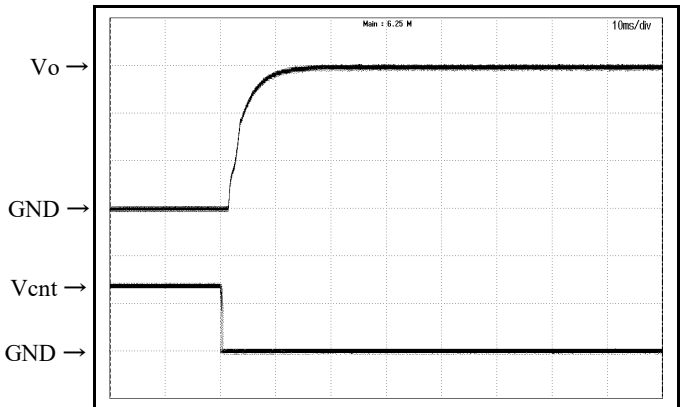


Vcnt:5V/DIV	Vo:5V/DIV
5s/DIV	

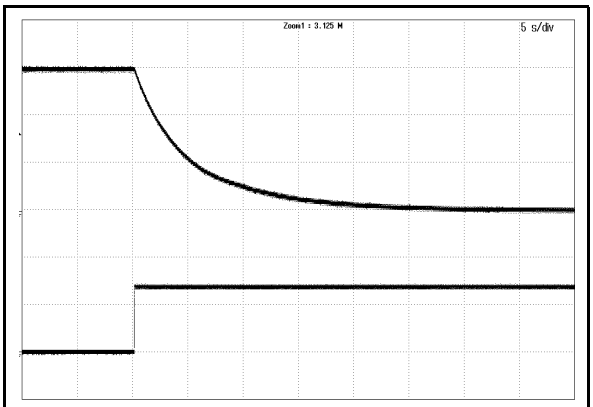
2.6 出力立ち上がり、立ち下がり特性（ON/OFFコントロール時）

Output rise and fall characteristics with ON/OFF CONTROL　　Conditions　　Vin : 110 VDC
Io : 0 %
Tbp : 25℃

15V

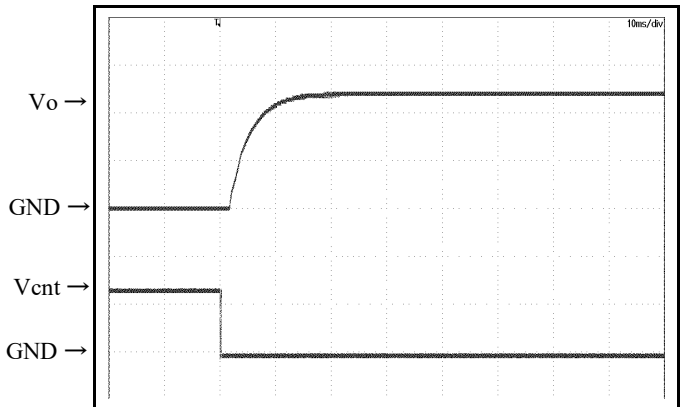


Vcnt:5V/DIV	Vo:5V/DIV
10ms/DIV	

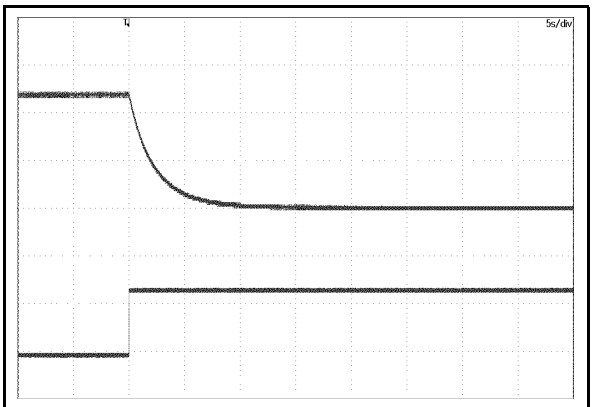


Vcnt:5V/DIV	Vo:5V/DIV
5s/DIV	

24V



Vcnt:5V/DIV	Vo:10V/DIV
10ms/DIV	

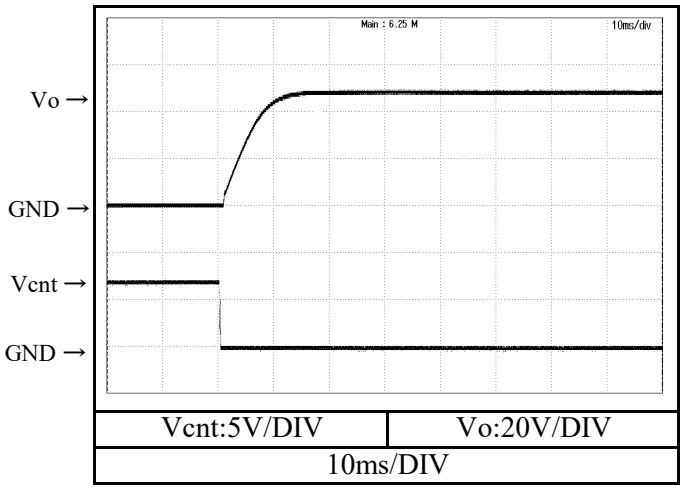


Vcnt:5V/DIV	Vo:10V/DIV
5s/DIV	

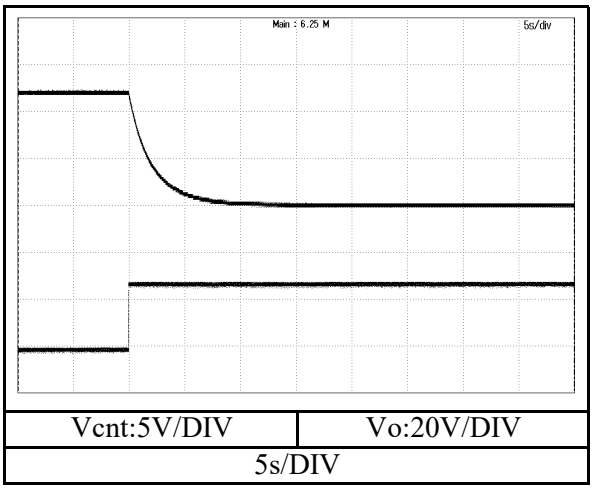
2.6 出力立ち上がり、立ち下がり特性（ON/OFFコントロール時）

Output rise and fall characteristics with ON/OFF CONTROL　　Conditions　　Vin : 110 VDC
Io : 0 %
Tbp : 25℃

48V



Vcnt:5V/DIV	Vo:20V/DIV
10ms/DIV	

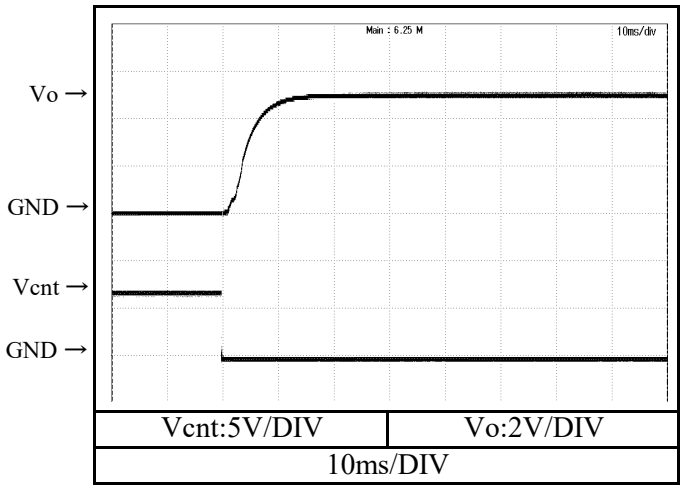


Vcnt:5V/DIV	Vo:20V/DIV
5s/DIV	

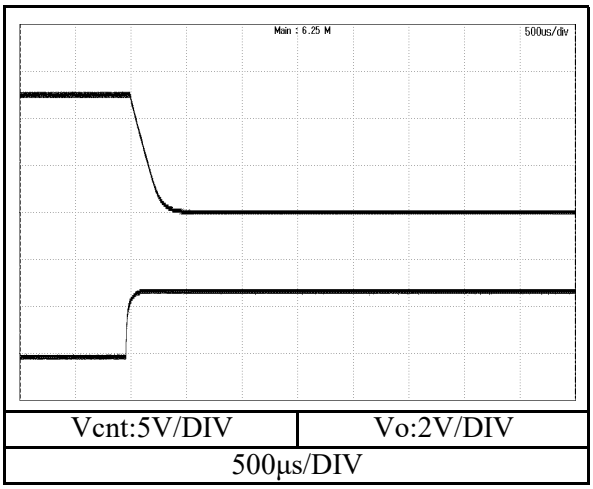
2.6 出力立ち上がり、立ち下がり特性（ON/OFFコントロール時）

Output rise and fall characteristics with ON/OFF CONTROL　　Conditions　　Vin : 110 VDC
Io : 100 %
Tbp : 25℃

5V

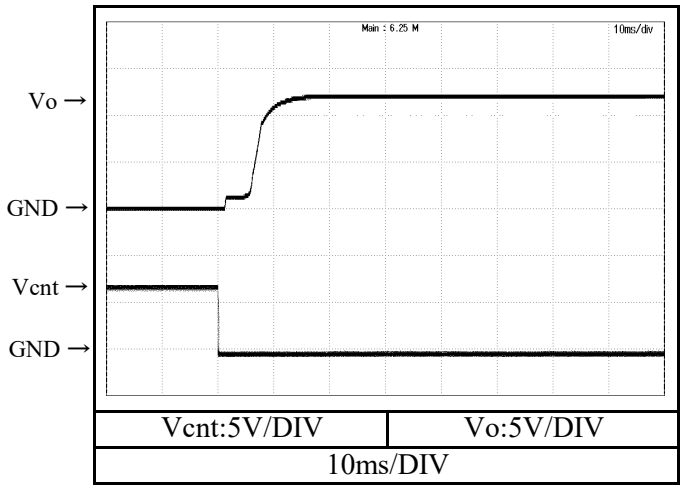


Vcnt:5V/DIV	Vo:2V/DIV
10ms/DIV	

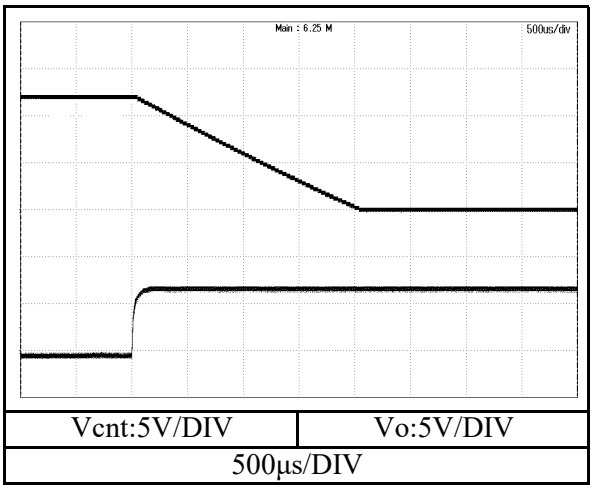


Vcnt:5V/DIV	Vo:2V/DIV
500µs/DIV	

12V



Vcnt:5V/DIV	Vo:5V/DIV
10ms/DIV	

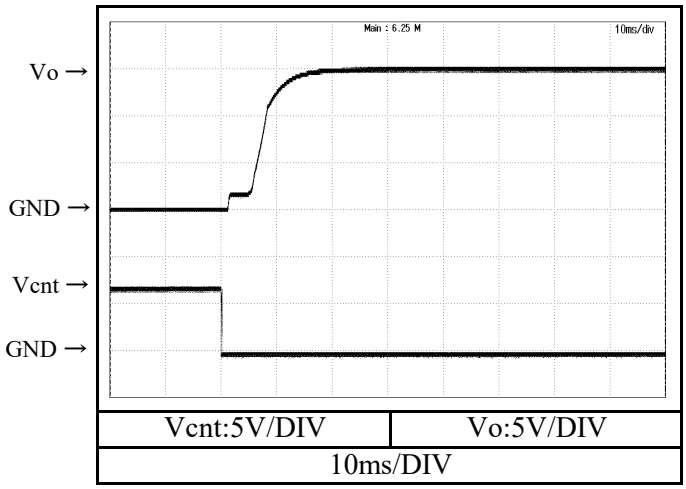


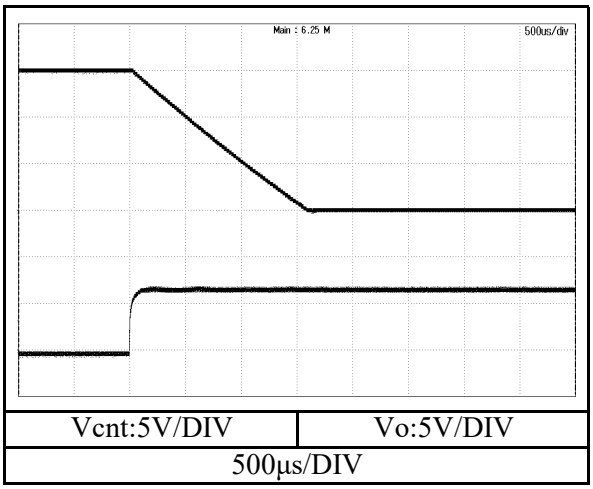
Vcnt:5V/DIV	Vo:5V/DIV
500µs/DIV	

2.6 出力立ち上がり、立ち下がり特性（ON/OFFコントロール時）

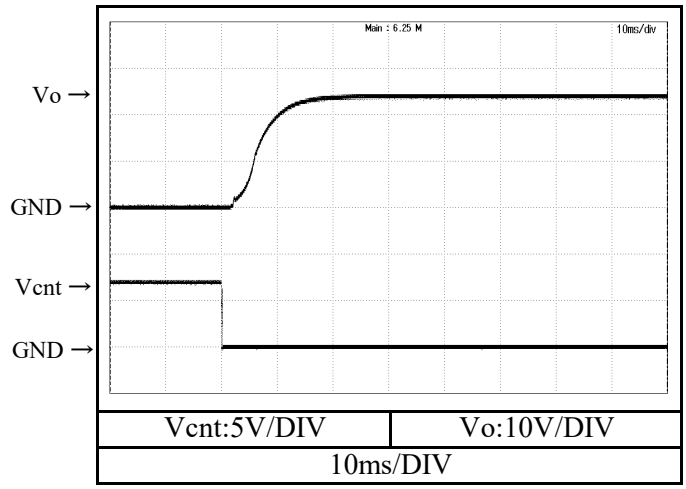
Output rise and fall characteristics with ON/OFF CONTROL　　Conditions　　Vin : 110 VDC
Io : 100 %
Tbp : 25℃

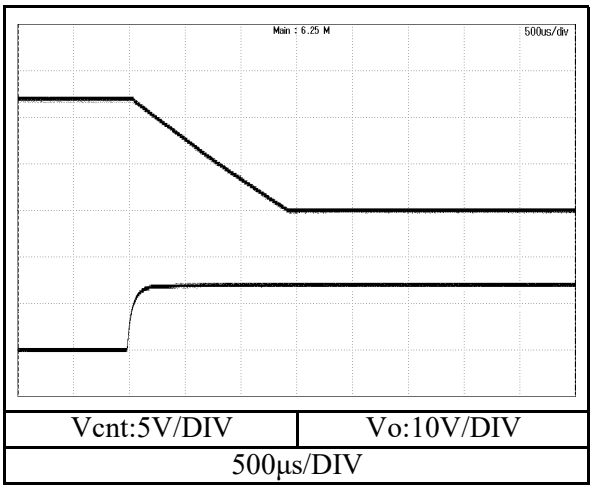
15V





24V

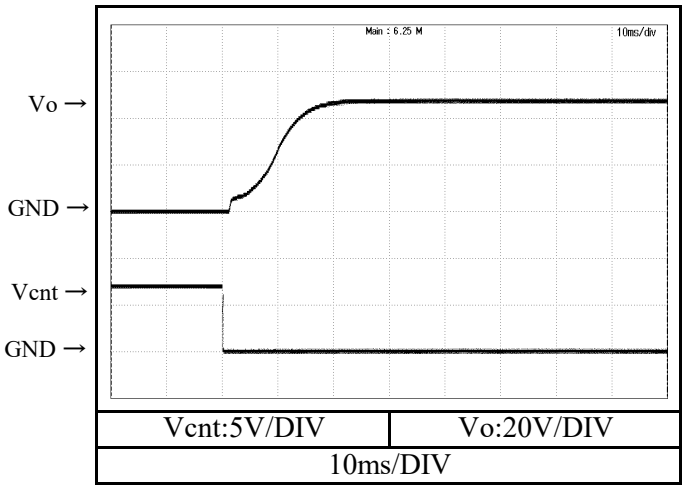




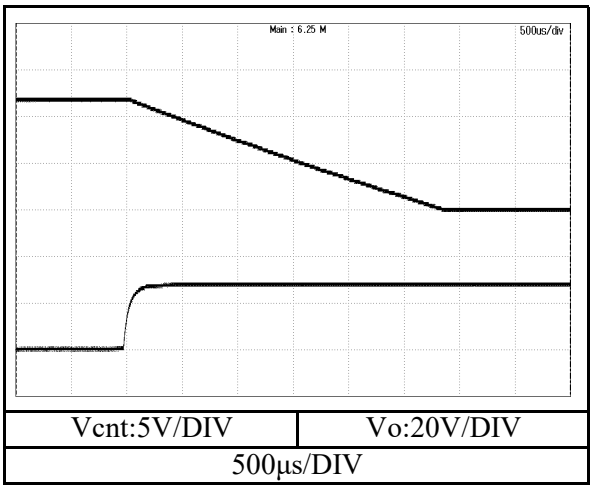
2.6 出力立ち上がり、立ち下がり特性（ON/OFFコントロール時）

Output rise and fall characteristics with ON/OFF CONTROL　　Conditions　　Vin : 110 VDC
Io : 100 %
Tbp : 25℃

48V



Vcnt:5V/DIV	Vo:20V/DIV
10ms/DIV	



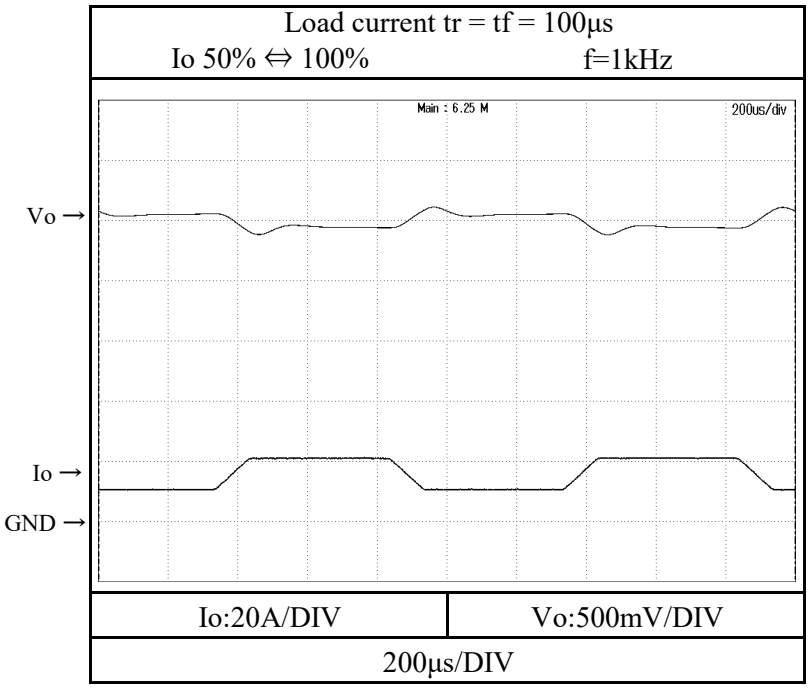
Vcnt:5V/DIV	Vo:20V/DIV
500µs/DIV	

2.7 過渡応答(負荷急変)特性

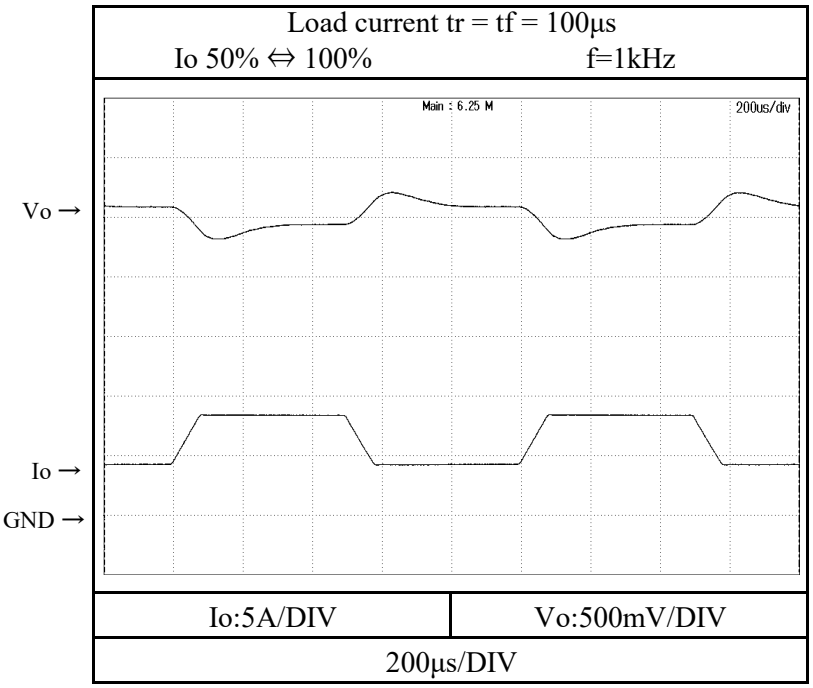
Dynamic load response characteristics

Conditions Vin : 110VDC
Tbp : 25℃

5V



12V

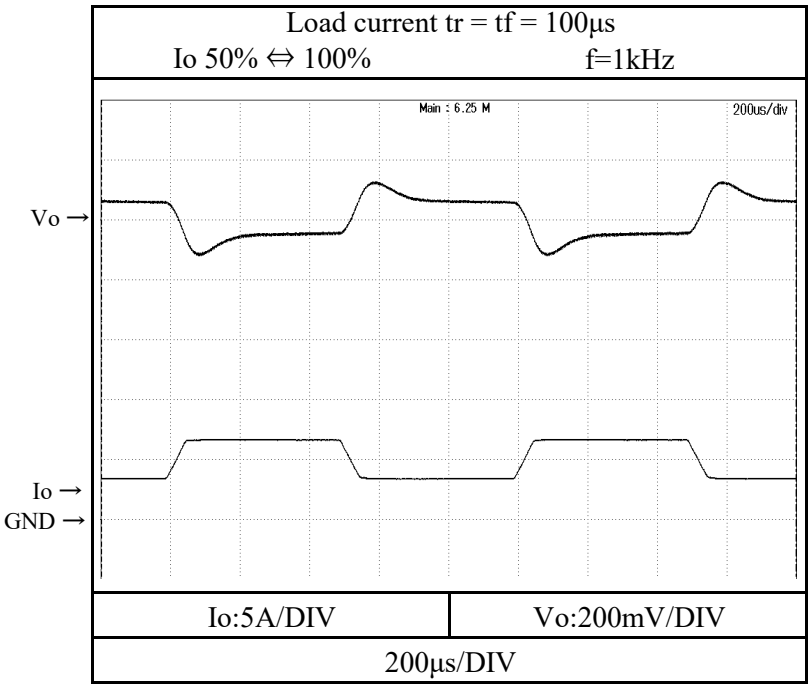


2.7 過渡応答(負荷急変)特性

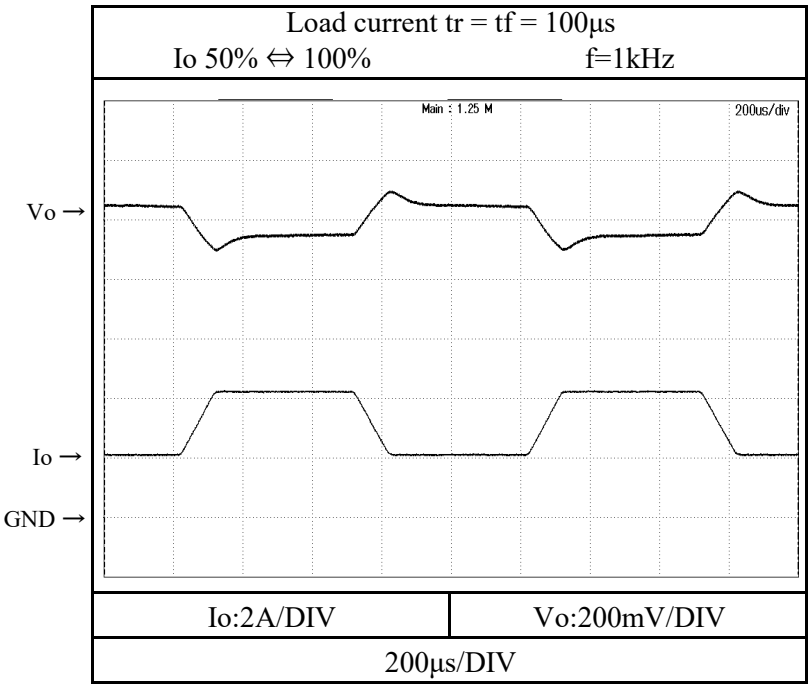
Dynamic load response characteristics

Conditions Vin : 110VDC
Tbp : 25℃

15V



24V

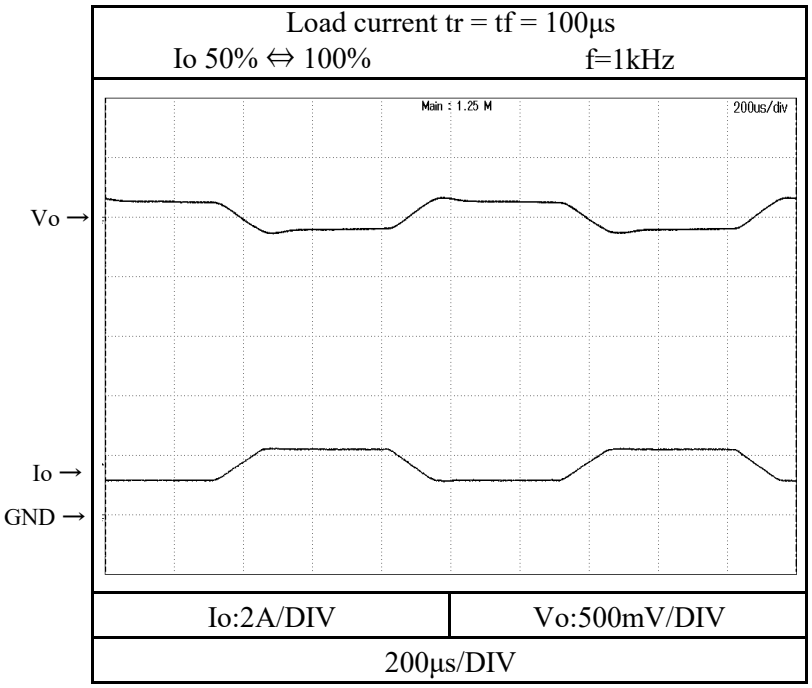


2.7 過渡応答(負荷急変)特性

Dynamic load response characteristics

Conditions Vin : 110VDC
Tbp : 25℃

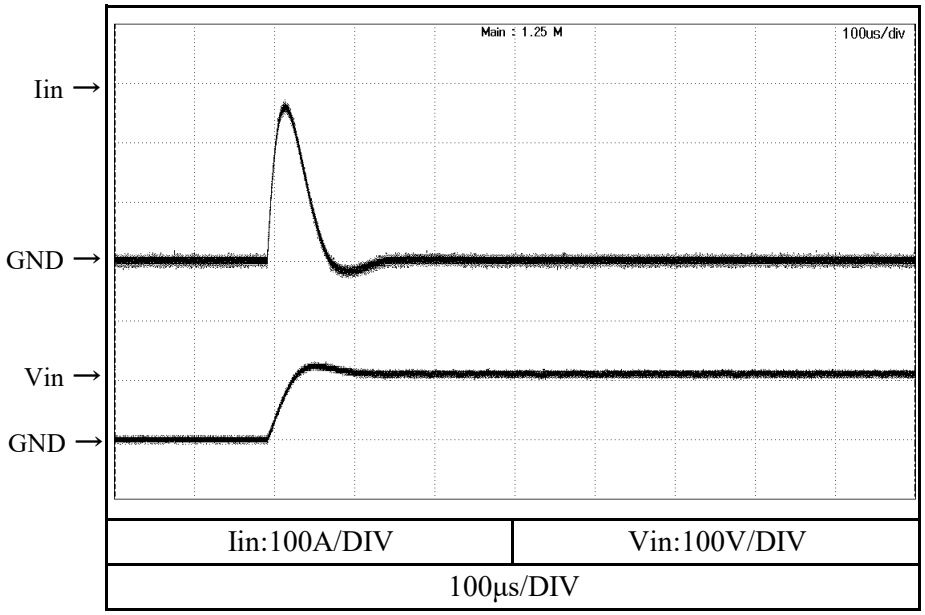
48V



2.8 入力サージ電流(突入電流)特性
Inrush current characteristics

Conditions Vin : 110 VDC
Io : 100%
Tbp : 25℃

48V

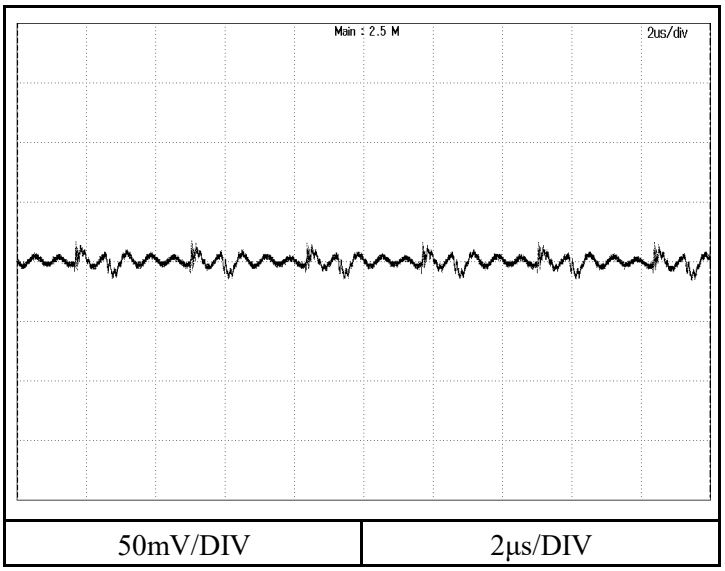


2.9 出力リップル・ノイズ波形

Output ripple and noise waveform

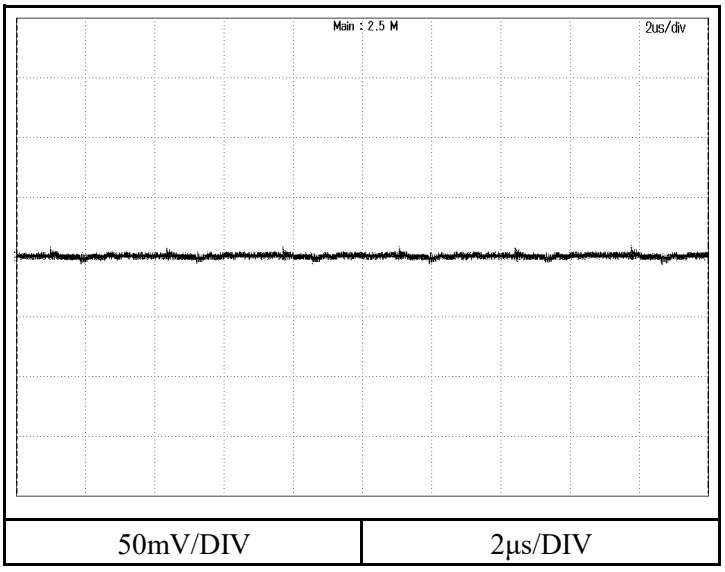
Conditions Vin : 110VDC
Io : 100%
Tbp : 25℃

5V



50mV/DIV	2μs/DIV

12V



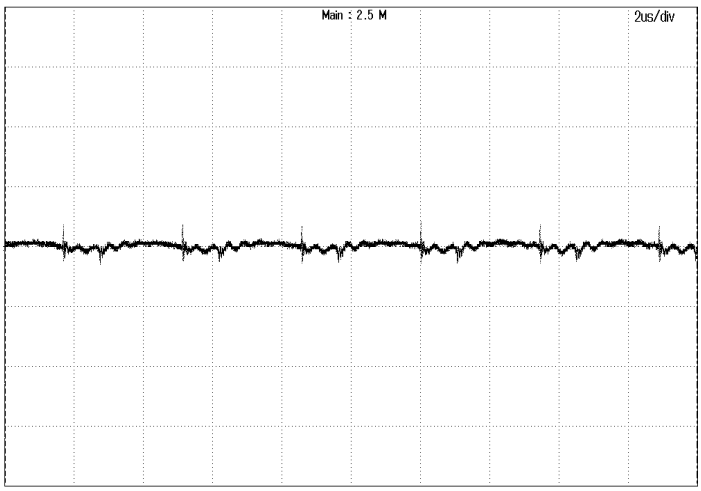
50mV/DIV	2μs/DIV

2.9 出力リップル・ノイズ波形

Output ripple and noise waveform

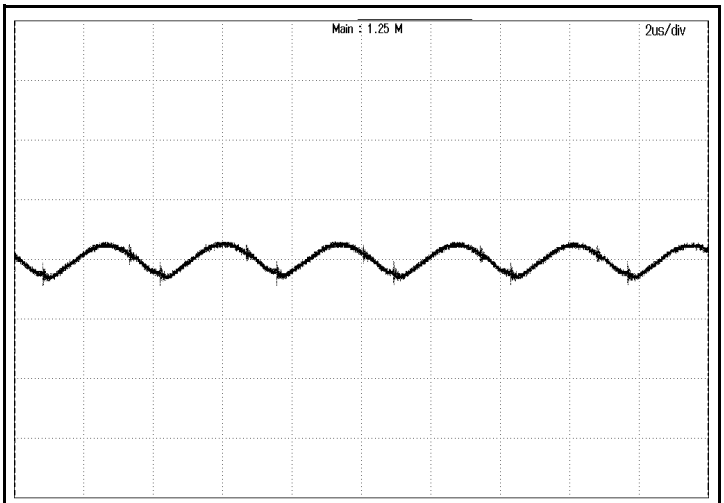
Conditions Vin : 110VDC
Io : 100%
Tbp : 25℃

15V



50mV/DIV	2μs/DIV

24V



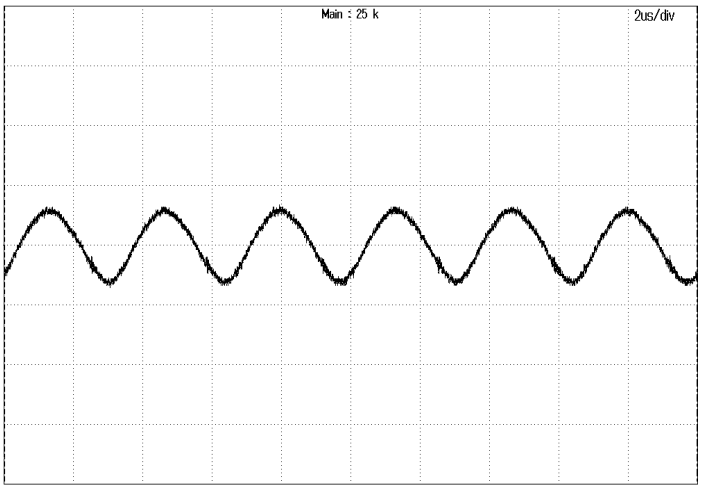
50mV/DIV	2μs/DIV

2.9 出力リップル・ノイズ波形

Output ripple and noise waveform

Conditions Vin : 110VDC
Io : 100%
Tbp : 25℃

48V



100mV/DIV	2μs/DIV

2.10 EMI特性

Electro-Magnetic Interference characteristics

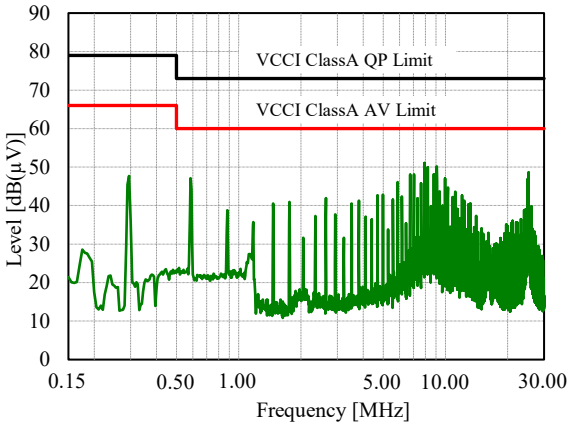
(a) 雑音端子電圧(帰還ノイズ)

Conducted Emission Noise

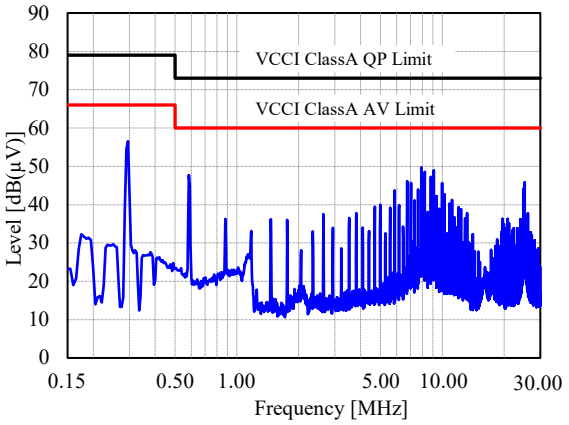
Conditions Vin : 110VDC
Io : 100%
Tbp : 25°C

5V

+Vin

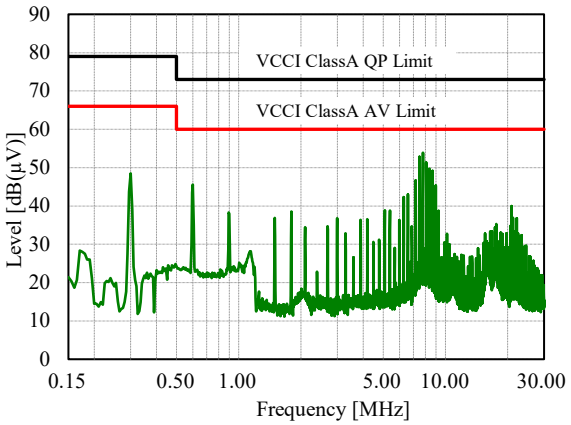


-Vin

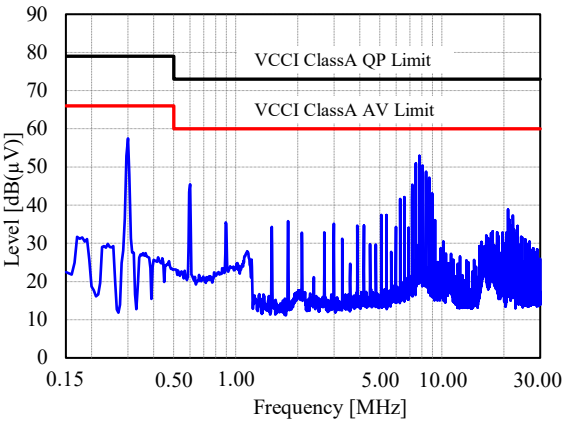


12V

+Vin

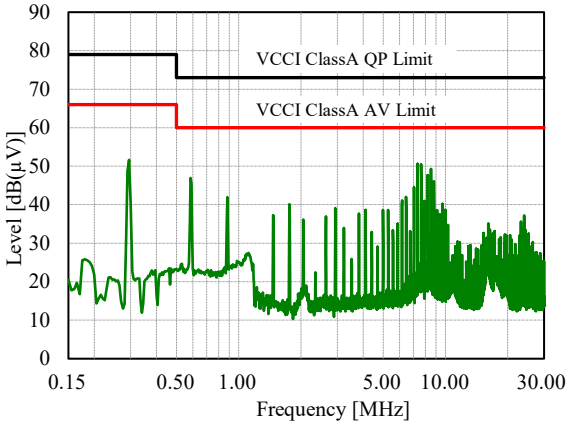


-Vin

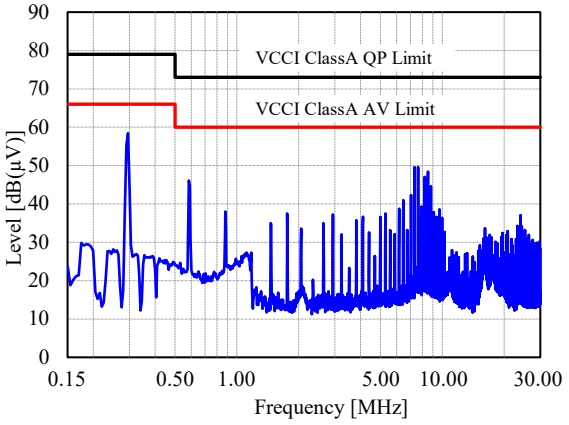


15V

+Vin



-Vin



2.10 EMI特性

Electro-Magnetic Interference characteristics

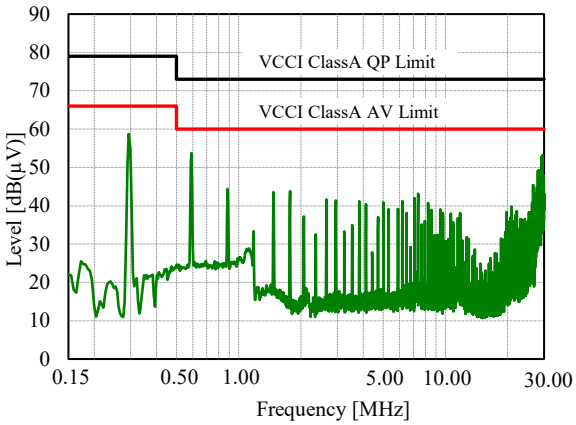
(a) 雑音端子電圧(帰還ノイズ)

Conducted Emission Noise

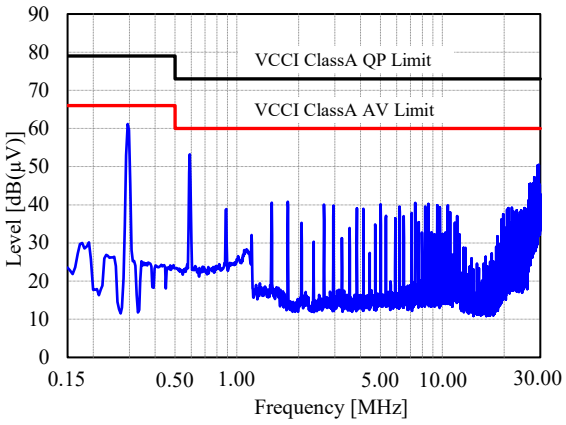
Conditions Vin : 110VDC
Io : 100%
Tbp : 25°C

24V

+Vin

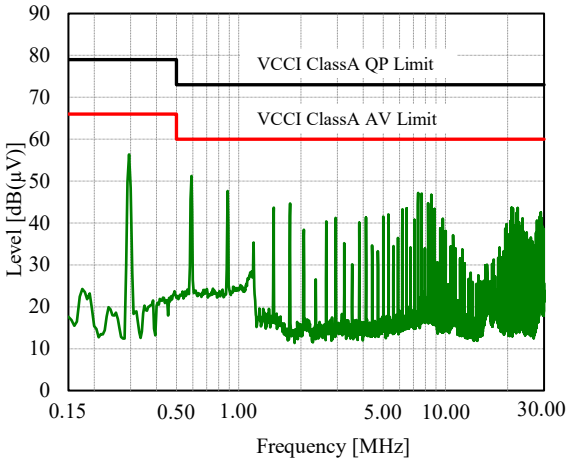


-Vin

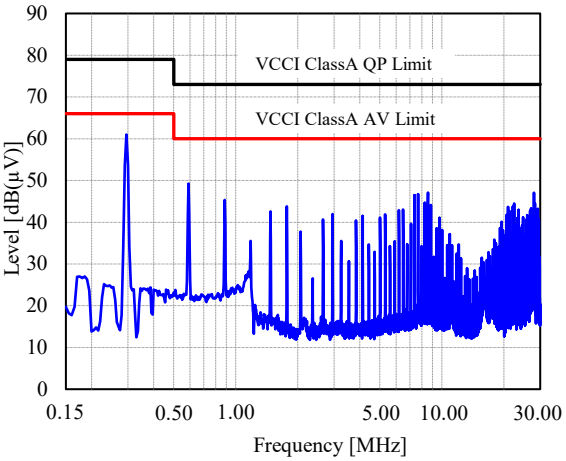


48V

+Vin



-Vin



2.10 EMI特性

Electro-Magnetic Interference characteristics

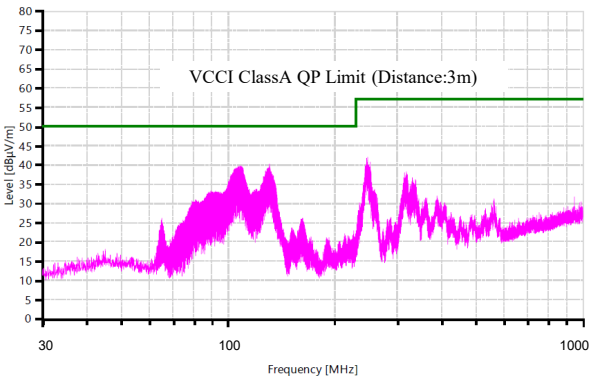
(b) 雑音電界強度(輻射ノイズ)

Radiated Emission Noise

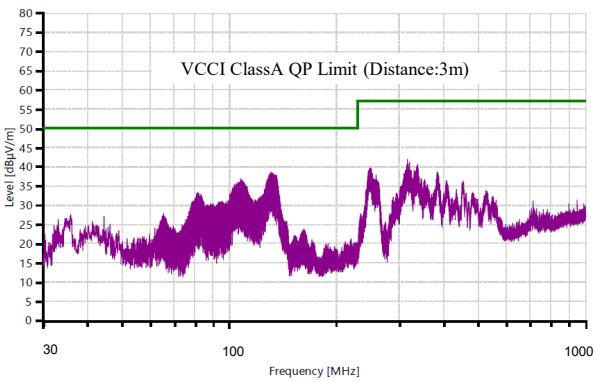
Conditions Vin : 110VDC
Io : 100%
Tbp : 25°C

5V

HORIZONTAL

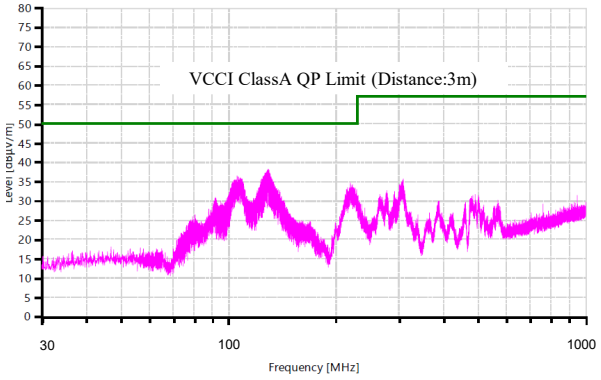


VERTICAL

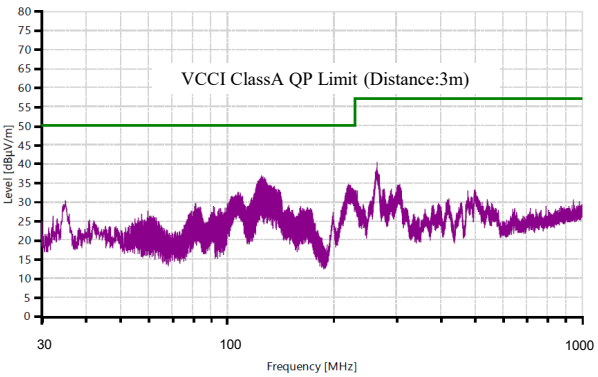


12V

HORIZONTAL

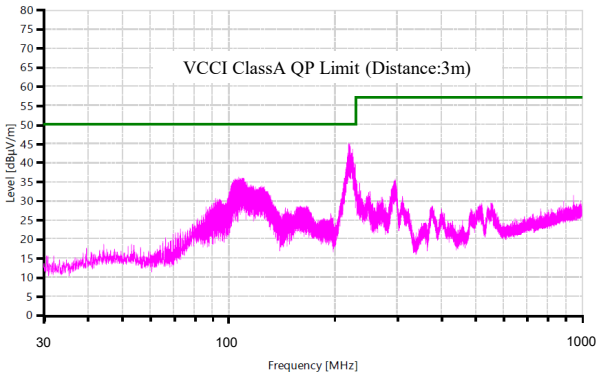


VERTICAL

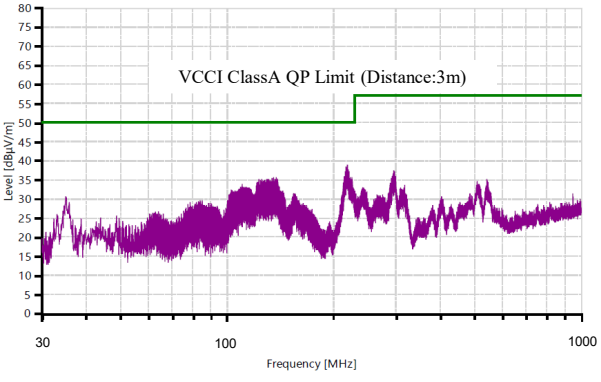


15V

HORIZONTAL



VERTICAL



2.10 EMI特性

Electro-Magnetic Interference characteristics

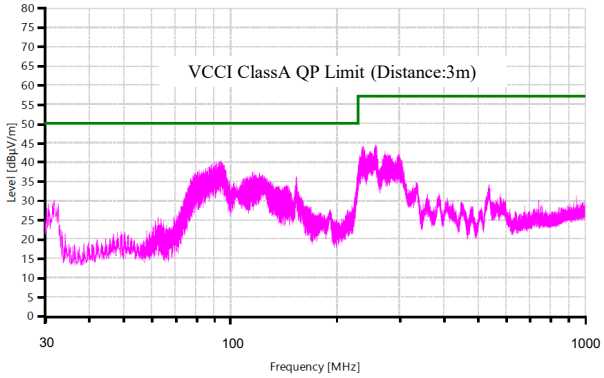
(b) 雑音電界強度(輻射ノイズ)

Radiated Emission Noise

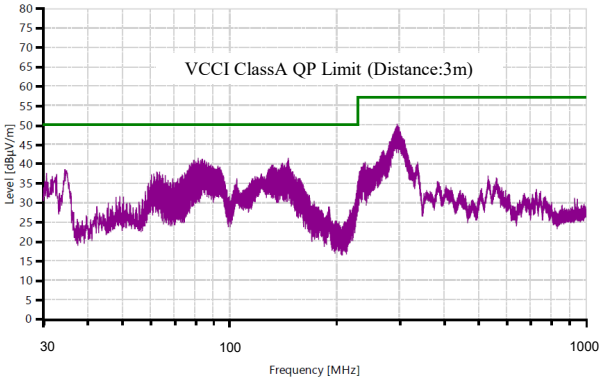
Conditions Vin : 110VDC
Io : 100%
Tbp : 25°C

24V

HORIZONTAL

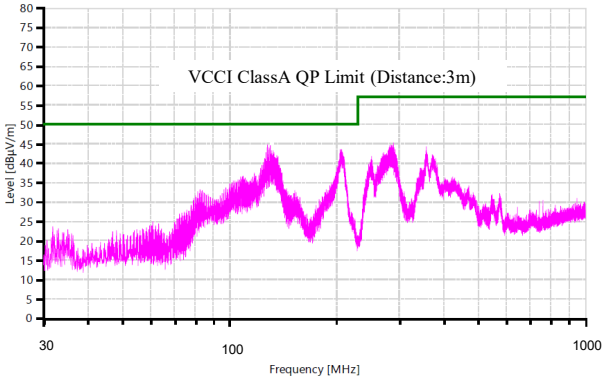


VERTICAL



48V

HORIZONTAL



VERTICAL